

# PCF2127AT

# Integrated RTC, TCXO and quartz crystal

Rev. 3 — 4 October 2012

**Product data sheet** 

### 1. General description

The PCF2127AT<sup>1</sup> is a CMOS<sup>2</sup> Real Time Clock (RTC) and calendar with an integrated Temperature Compensated Crystal (Xtal) Oscillator (TCXO) and a 32.768 kHz quartz crystal optimized for very high accuracy and very low power consumption. The PCF2127AT has 512 bytes of general purpose static RAM, a selectable I<sup>2</sup>C-bus or SPI-bus, a backup battery switch-over circuit, a programmable watchdog function, a timestamp function, and many other features.

### 2. Features and benefits

- Temperature Compensated Crystal Oscillator (TCXO) with integrated capacitors
- Typical accuracy: ±3 ppm from -15 °C to +60 °C
- Integration of a 32.768 kHz quartz crystal and oscillator in the same package
- Provides year, month, day, weekday, hours, minutes, seconds, and leap year correction
- 512 bytes of general purpose static RAM
- Timestamp function
  - with interrupt capability
  - detection of two different events on one multilevel input pin (for example, for tamper detection)
- Two line bidirectional 400 kHz Fast-mode I<sup>2</sup>C-bus interface (I<sub>OL</sub> = 3 mA at pin SDA/CE)
- 3 line SPI-bus with separate data input and output (maximum speed 6.5 Mbit/s)
- Battery backup input pin and switch-over circuitry
- Battery backed output voltage pin
- Battery low detection function
- Extra power fail detection function with input and output pins
- Power-On Reset Override (PORO)
- Oscillator stop detection function
- Interrupt output and system reset pin (open-drain)
- Programmable 1 second or 1 minute interrupt
- Programmable countdown timer with interrupt capability
- Programmable watchdog timer with interrupt and reset capability
- Programmable alarm function with interrupt capability
- Programmable square wave open-drain output pin

<sup>2.</sup> The definition of the abbreviations and acronyms used in this data sheet can be found in Section 19.



<sup>1.</sup> As well as the PCF2129.

### Integrated RTC, TCXO and quartz crystal

- Clock operating voltage: 1.2 V to 4.2 V
- Low supply current: typical 0.65 μA at V<sub>DD</sub> = 3.0 V and T<sub>amb</sub> = 25 °C

# 3. Applications

- Electronic metering for electricity, water, and gas
- Timekeeping instruments with high precision
- GPS equipment to reduce time to first fix
- Applications that require an accurate process timing
- Products with long automated unattended operation time

### 4. Ordering information

Table 1. Ordering information

Type number	Package						
	Name	Description	Version				
PCF2127AT	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1				

### 4.1 Ordering options

Table 2. Ordering options

Type number	IC revision	Sales item (12NC)	Delivery form
PCF2127AT/1	1	935290953512	tube, dry pack
		935290953518	tape and reel, 13 inch, dry pack

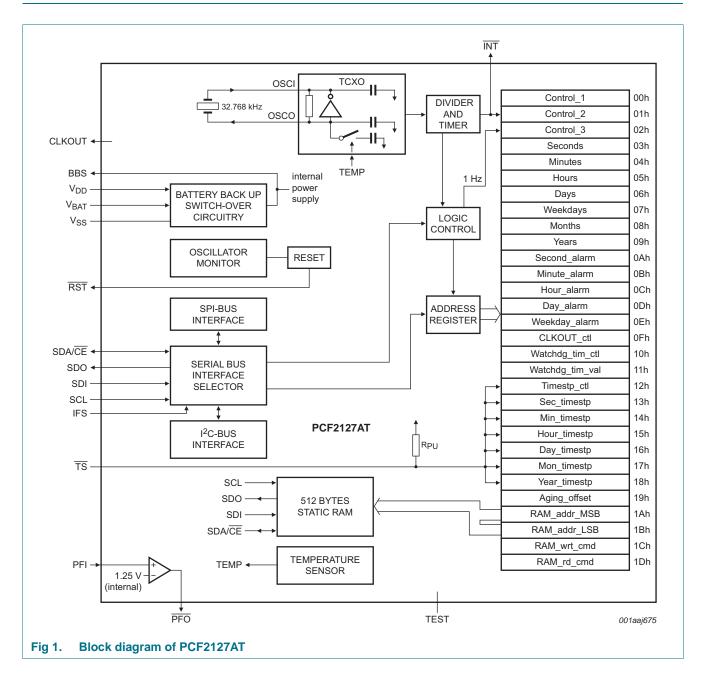
## 5. Marking

Table 3. Marking codes

Type number	Marking code
PCF2127AT/1	PCF2127AT

### Integrated RTC, TCXO and quartz crystal

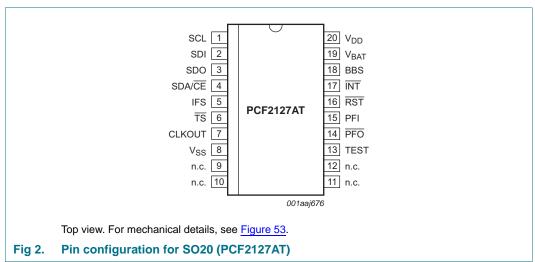
## 6. Block diagram



Integrated RTC, TCXO and quartz crystal

# 7. Pinning information

### 7.1 Pinning



7.2 Pin description

### Table 4. Pin description of SO20 (PCF2127AT)

	=	
Symbol	Pin	Description
SCL	1	combined serial clock input for both I $^2\text{C-bus}$ and SPI-bus; may float when SDA/ $\overline{\text{CE}}$ inactive
SDI	2	serial data input for SPI-bus; may float when SDA/CE inactive
SDO	3	serial data output for SPI-bus, push-pull
SDA/CE	4	combined serial data input and output for the I <sup>2</sup> C-bus and chip enable input (active LOW) for the SPI-bus
IFS	5	interface selector input
		connect to pin V <sub>SS</sub> to select the SPI-bus
		connect to pin BBS to select the I <sup>2</sup> C-bus
TS	6	timestamp input (active LOW) with 200 $k\Omega$ internal pull-up resistor (R $_{PU})$
CLKOUT	7	clock output (open-drain)
V <sub>SS</sub>	8	ground supply voltage
n.c.	9 to 12	not connected; do not connect; do not use as feed through
TEST	13	do not connect; do not use as feed through
PFO	14	power fail output (open-drain; active LOW)
PFI	15	power fail input
RST	16	reset output (open-drain; active LOW)
ĪNT	17	interrupt output (open-drain; active LOW)
BBS	18	output voltage (battery backed)
$V_{BAT}$	19	battery supply voltage (backup)
$V_{DD}$	20	supply voltage

Integrated RTC, TCXO and quartz crystal

### 8. Functional description

The PCF2127AT is a Real Time Clock (RTC) and calendar with an on-chip Temperature Compensated Crystal (Xtal) Oscillator (TCXO) and a 32.768 kHz quartz crystal integrated.

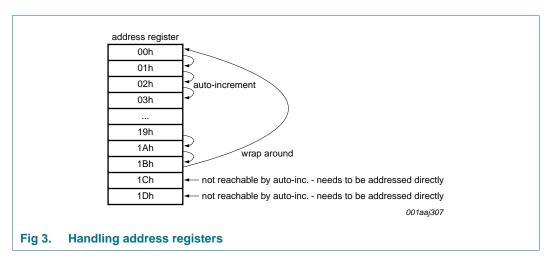
Address and data are transferred by a selectable 400 kHz Fast-mode I<sup>2</sup>C-bus or a 3 line SPI-bus with separate data input and output (see <u>Section 9</u>). The maximum speed of the SPI-bus is 6.5 Mbit/s.

The PCF2127AT has a backup battery input pin and backup battery switch-over circuit which monitors the main power supply. The backup battery switch-over circuit automatically switches to the backup battery when a power failure condition is detected (see <u>Section 8.6.1</u>). Accurate timekeeping is maintained even when the main power supply is interrupted.

A battery low detection circuit monitors the status of the battery (see <u>Section 8.6.3</u>). When the battery voltage drops below a certain threshold value, a flag is set to indicate that the battery must be replaced soon. This ensures the integrity of the data during periods of battery backup.

### 8.1 Register overview

The PCF2127AT contains an auto-incrementing address register: the built-in address register will increment automatically after each read or write of a data byte up to the register 1Bh. After register 1Bh, the auto-incrementing will wrap around to address 00h (see Figure 3).



- The first three registers (memory address 00h, 01h, and 02h) are used as control registers (see Section 8.2).
- The memory addresses 03h through to 09h are used as counters for the clock function (seconds up to years). The date is automatically adjusted for months with fewer than 31 days, including corrections for leap years. The clock can operate in 12-hour mode with an AM/PM indication or in 24-hour mode (see Section 8.9).
- Addresses 0Ah through 0Eh define the alarm function. It can be selected that an interrupt is generated when an alarm event occurs (see <u>Section 8.10</u>).

PCF2127AT

#### Integrated RTC, TCXO and quartz crystal

- The register 0Fh defines the temperature measurement period and the clock out mode. The temperature measurement can be selected from every 4 minutes (default) down to every 30 seconds (see <u>Table 10</u>). CLKOUT frequencies of 32.768 kHz (default) down to 1 Hz for use as system clock, microcontroller clock, and so on, can be chosen (see <u>Table 11</u>).
- Address registers 10h and 11h are used for the watchdog and countdown timer functions. The watchdog timer has four selectable source clocks allowing for timer periods from less than 1 ms to greater than 4 hours (see <u>Table 37</u>). Either the watchdog timer **or** the countdown timer can be enabled (see <u>Section 8.11</u>). For the watchdog timer, it is possible to select whether an interrupt or a pulse on the reset pin will be generated when the watchdog times out. For the countdown timer, it is only possible that an interrupt will be generated at the end of the countdown.
- Address registers 12h to 18h are used for the timestamp function. When the trigger event happens, the actual time is saved in the timestamp registers (see Section 8.12).
- Address register 19h is used for the correction of the crystal aging effect (see Section 8.4.1).
- Address registers 1Ah and 1Bh define the RAM address. Address register 1Ch
   (RAM\_wrt\_cmd) is the RAM write command; address register 1Dh (RAM\_rd\_cmd) is
   the RAM read command. Data is transferred to or from the RAM by the serial interface
   (see <u>Section 8.5</u>).
- The registers Seconds, Minutes, Hours, Days, Months, and Years are all coded in Binary Coded Decimal (BCD) format to simplify application use. Other registers are either bit-wise or standard binary.

When one of the RTC registers is written or read, the content of all counters is temporarily frozen. This prevents a faulty writing or reading of the clock and calendar during a carry condition (see Section 8.9.8).

### Integrated RTC, TCXO and quartz crystal

Table 5. Register overview

Bit positions labeled as - are not implemented and will return a 0 when read. Bit T must always be written with logic 0. Bits labeled as X are undefined at power-on and unchanged by subsequent resets.

Address Register name		Bit									
		7	6	5	4	3	2	1	0		
Control re	egisters				1		'		1		
00h	Control_1	EXT_ TEST	Т	STOP	TSF1	POR_ OVRD	12_24	MI	SI	0000 0000	
01h	Control_2	MSF	WDTF	TSF2	AF	CDTF	TSIE	AIE	CDTIE	0000 0000	
02h	Control_3	PWRMN	G[2:0]		BTSE	BF	BLF	BIE	BLIE	0000 0000	
Time and	date registers										
03h	Seconds	OSF			SEC	ONDS (0	to 59)			1XXX XXXX	
04h	Minutes	-			MIN	IUTES (0	to 59)			- XXX XXXX	
05h	Hours	-	-	AMPM	HOURS	(1 to 12)	in 12 h m	ode		XX XXXX	
				HOURS	(0 to 23) i	n 24 h mo	de			XX XXXX	
06h	Days	-	-			DAYS	(1 to 31)			XX XXXX	
07h	Weekdays	-	-	-	-	-	WE	EKDAYS	(0 to 6)	XXX	
08h	Months	-	-	-		MC	NTHS (1	to 12)		X XXXX	
09h	Years				YEARS	(0 to 99)				XXXX XXXX	
Alarm reg	jisters										
0Ah	Second_alarm	AE_S			SECON	D_ALARN	/I (0 to 59)			1XXX XXXX	
0Bh	Minute_alarm	AE_M			MINUTI	E_ALARM	l (0 to 59)			1XXX XXXX	
0Ch	Hour_alarm	AE_H	-	AMPM	HOUR_	ALARM (1	to 12) in	12 h mod	е	1 - XX XXX	
			- HOUR_ALARM (0 to 23) in 24 h mode						1 - XX XXX		
0Dh	Day_alarm	AE_D	-		[	DAY_ALA	RM (1 to 3	31)		1 - XX XXX	
0Eh	Weekday_alarm	AE_W	-	-	-	-	WEEK	AY_ALAI	RM (0 to 6)	1 XXX	
CLKOUT	control register										
0Fh	CLKOUT_ctl	TCR[1:0]		-	-	-	COF[2:0	0]		00 000	
Watchdo	g registers										
10h	Watchdg_tim_ctl	WD_CD[	1:0]	TI_TP	-	-	-	TF[1:0]		000 11	
11h	Watchdg_tim_val	WATCHE	G_TIM_\	/AL[7:0]						XXXX XXXX	
Timestam	p registers										
12h	Timestp_ctl	TSM	TSOFF	-	1_0_16	_TIMESTI	P[4:0]			00 - X XXXX	
13h	Sec_timestp	-	SECON	D_TIMEST	TP (0 to 59	9)				- XXX XXXX	
14h	Min_timestp	-	MINUTE	_TIMESTI	P (0 to 59	)				- XXX XXXX	
15h	Hour_timestp	-	-	AMPM	HOUR_	TIMESTP	(1 to 12) i	n 12 h m	ode	XX XXXX	
			HOUR_TIMESTP (0 to 23) in 24 h mode						XX XXXX		
16h	Day_timestp	-	-	DAY_TIN	/IESTP (1	to 31)				XX XXXX	
17h	Mon_timestp	-	-	-	MONTH	_TIMEST	P (1 to 12	)		X XXXX	
18h	Year_timestp	YEAR_T	IMESTP (	0 to 99)	1					XXXX XXXX	
Aging off	set register	1									
19h	Aging_offset	-	-	-	-	AO[3:0]				1000	

### Integrated RTC, TCXO and quartz crystal

 Table 5.
 Register overview ...continued

Bit positions labeled as - are not implemented and will return a 0 when read. Bit T must always be written with logic 0. Bits labeled as X are undefined at power-on and unchanged by subsequent resets.

Address	Register name Bit								Reset value		
			6	5	4	3	2	1	0		
RAM regi	RAM registers							'			
1Ah	RAM_addr_MSB	-	-	-	-	-	-	-	RA8	0	
1Bh	RAM_addr_LSB	RA[7:0]								0000 0000	
1Ch	RAM_wrt_cmd	X	X	X	X	X	X	X	X	XXXX XXXX	
1Dh	RAM_rd_cmd	X	X	X	X	X	X	X	X	XXXX XXXX	

### Integrated RTC, TCXO and quartz crystal

### 8.2 Control registers

The first 3 registers of the PCF2127AT, with the addresses 00h, 01h, and 02h, are used as control registers.

### 8.2.1 Register Control\_1

Table 6. Control\_1 - control and status register 1 (address 00h) bit description

Bit	Symbol	Value		Description	Reference
7	EXT_TEST	0	[1]	normal mode	Section 8.14
		1		external clock test mode	
6	T	0	[2]	unused	-
5	STOP	0	[1]	RTC source clock runs	Section 8.15
		1		RTC clock is stopped;	
				RTC divider chain flip-flops are asynchronously set logic 0;	
				CLKOUT at 32.768 kHz, 16.384 kHz, or 8.192 kHz is still available	
4	TSF1	0	<u>[1]</u>	no timestamp interrupt generated	Section 8.12.1
		1		flag set when TS input is driven to an intermediate level between power supply and ground;	
				flag must be cleared to clear interrupt	
3	POR_OVRD	0	[1]	Power-On Reset Override (PORO) facility disabled;	Section 8.8.2
				set logic 0 for normal operation	
		1		PORO enabled	
2	12_24	0	[1]	24 hour mode selected	Table 23
		1		12 hour mode selected	
1	MI	0	[1]	minute interrupt disabled	Section 8.13
		1		minute interrupt enabled	
0	SI	0	[1]	second interrupt disabled	
		1		second interrupt enabled	

<sup>[1]</sup> Default value.

<sup>[2]</sup> When writing to the register this bit always has to be set logic 0.

### Integrated RTC, TCXO and quartz crystal

### 8.2.2 Register Control\_2

Table 7. Control\_2 - control and status register 2 (address 01h) bit description

		COILLIC		P	
Bit	Symbol	Value		Description	Reference
7	MSF	0	[1]	no minute or second interrupt generated	Section 8.13
		1		flag set when minute or second interrupt generated;	
				flag must be cleared to clear interrupt	
6	WDTF	0	[1]	no watchdog timer interrupt or reset generated	<u>Section 8.13.4</u>
		1		flag set when watchdog timer interrupt or reset generated;	
				flag cannot be cleared by command (read-only)	
5	TSF2	0	[1]	no timestamp interrupt generated	Section 8.12.1
		1		flag set when $\overline{TS}$ input is driven to ground;	
				flag must be cleared to clear interrupt	
4	AF	0	[1]	no alarm interrupt generated	Section 8.10.6
		1		flag set when alarm triggered;	
				flag must be cleared to clear interrupt	
3	CDTF	0	[1]	no countdown timer interrupt generated	<u>Section 8.11.4</u>
		1		flag set when countdown timer interrupt generated;	
				flag must be cleared to clear interrupt	
2	TSIE	0	[1]	no interrupt generated from timestamp flag	Section 8.13.6
		1		interrupt generated when timestamp flag set	
1	AIE	0	[1]	no interrupt generated from the alarm flag	Section 8.13.5
		1		interrupt generated when alarm flag set	
0	CDTIE	0	[1]	no interrupt generated from countdown timer flag	Section 8.13.2
		1		interrupt generated when countdown timer flag set	

<sup>[1]</sup> Default value.

### Integrated RTC, TCXO and quartz crystal

### 8.2.3 Register Control\_3

Table 8. Control\_3 - control and status register 3 (address 02h) bit description

			P		
Bit	Symbol	Value		Description	Reference
7 to 5	PWRMNG[2:0]	[1]		control of the battery switch-over, battery low detection, and extra power fail detection functions	Section 8.6
4	BTSE	0	[2]	no timestamp when battery switch-over occurs	<u>Section 8.12.4</u>
		1		time-stamped when battery switch-over occurs	
3	BF	0	[2]	no battery switch-over interrupt generated	Section 8.6.1
		1		flag set when battery switch-over occurs; flag must be cleared to clear interrupt	
2	BLF	0	[2]	battery status ok; no battery low interrupt generated	Section 8.6.3
		1		battery status low; flag cannot be cleared by command	
1	BIE	0	[2]	no interrupt generated from the battery flag (BF)	Section 8.13.7
		1		interrupt generated when BF is set	
0	BLIE	0	[2]	no interrupt generated from battery low flag (BLF)	Section 8.13.8
		1		interrupt generated when BLF is set	

<sup>[1]</sup> Values see <u>Table 18</u>.

<sup>[2]</sup> Default value.

#### Integrated RTC, TCXO and quartz crystal

### 8.3 Register CLKOUT\_ctl

Table 9. CLKOUT\_ctl - CLKOUT control register (address 0Fh) bit description

Bit	Symbol	Value	Description
7 to 6	TCR[1:0]	see <u>Table 10</u>	temperature measurement period
5 to 3	-	-	unused
2 to 0	COF[2:0]	see <u>Table 11</u>	CLKOUT frequency selection

#### 8.3.1 Temperature compensated crystal oscillator

The frequency of tuning fork quartz crystal oscillators is temperature-dependent. In the PCF2127AT, the frequency deviation caused by temperature variation is corrected by adjusting the load capacitance of the crystal oscillator.

The load capacitance is changed by switching between two load capacitance values using a modulation signal with a programmable duty cycle. In order to compensate the spread of the quartz parameters every chip is factory calibrated.

The frequency accuracy can be evaluated by measuring the frequency of the square wave signal available at the output pin CLKOUT. However, the selection of  $f_{CLKOUT} = 32.768$  kHz (default value) leads to inaccurate measurements. Accurate frequency measurement occurs when  $f_{CLKOUT} = 16.384$  kHz or lower is selected (see Table 11).

#### 8.3.1.1 Temperature measurement

The PCF2127AT has a temperature sensor circuit used to perform the temperature compensation of the frequency. The temperature is measured immediately after power-on and then periodically with a period set by the temperature conversion rate TCR[1:0] in the register CLKOUT\_ctl.

Table 10. Temperature measurement period

TCR[1:0]		Temperature measurement period
00	<u>[1]</u>	4 min
01		2 min
10		1 min
11		30 seconds

<sup>[1]</sup> Default value.

#### 8.3.2 Clock output

A programmable square wave is available at pin CLKOUT. Operation is controlled by the COF[2:0] control bits in register CLKOUT\_ctl. Frequencies of 32.768 kHz (default) down to 1 Hz can be generated for use as system clock, microcontroller clock, charge pump input, or for calibrating the oscillator.

CLKOUT is an open-drain output and enabled at power-on. When disabled, the output is high-impedance.

The duty cycle of the selected clock is not controlled, however, due to the nature of the clock generation all but the 32.768 kHz frequencies will be 50 : 50.

### Integrated RTC, TCXO and quartz crystal

Table 11. CLKOUT frequency selection

COF[2:0]	CLKOUT frequency (Hz)	Typical duty cycle <sup>[1]</sup>
000[2]	32768	60:40 to 40:60
001	16384	50 : 50
010	8192	50 : 50
011	4096	50 : 50
100	2048	50 : 50
101	1024	50 : 50
110	1	50 : 50
111	CLKOUT = high-Z	-

<sup>[1]</sup> Duty cycle definition: % HIGH-level time : % LOW-level time.

<sup>[2]</sup> Default value.

### Integrated RTC, TCXO and quartz crystal

### 8.4 Register Aging\_offset

Table 12. Aging\_offset - crystal aging offset register (address 19h) bit description

Bit	Symbol	Value	Description
7 to 4	-	-	unused
3 to 0	AO[3:0]	see Table 13	aging offset value

### 8.4.1 Crystal aging correction

The PCF2127AT has an offset register Aging\_offset to correct the crystal aging effects<sup>3</sup>.

The accuracy of the frequency of a quartz crystal depends on its aging. The aging offset adds an adjustment, positive or negative, in the temperature compensation circuit which allows correcting the aging effect.

At 25 °C, the aging offset bits allow a frequency correction of typically 1 ppm per AO[3:0] value, from –7 ppm to +8 ppm.

Table 13. Frequency correction at 25 °C, typical

AO[3:0]					
Decimal	Binary	Binary			
0	0000		+8		
1	0001		+7		
2	0010		+6		
3	0011		+5		
4	0100		+4		
5	0101		+3		
6	0110		+2		
7	0111		+1		
8	1000	<u>[1]</u>	0		
9	1001		-1		
10	1010		-2		
11	1011		-3		
12	1100		-4		
13	1101		<b>-</b> 5		
14	1110		-6		
15	1111		<b>-7</b>		

<sup>[1]</sup> Default value.

<sup>3.</sup> For further information please refer to the application note Ref. 3 "AN10857".

#### Integrated RTC, TCXO and quartz crystal

### 8.5 General purpose 512 bytes static RAM

The PCF2127AT contains a general purpose 512 bytes static RAM. This integrated SRAM is battery backed and can therefore be used to store data which is essential for the application to survive a power outage.

9 bits, RA[8:0], define the RAM address pointer in registers RAM\_addr\_MSB and RAM\_addr\_LSB. The register address pointer increments after each read or write automatically up to 1Bh and then wraps around to address 00h (see Figure 3 on page 5).

Data is transferred to or from the RAM by the interface. To write to the RAM, the register RAM\_wrt\_cmd, to read from the RAM the register RAM\_rd\_cmd must be addressed explicitly.

#### 8.5.1 Register RAM addr MSB

Table 14. RAM\_addr\_MSB - RAM address MSB register (address 1Ah) bit description

Bit	Symbol	Description	
7 to 1	-	unused	
0	RA8	RAM address, MSB (9 <sup>th</sup> bit)	

### 8.5.2 Register RAM\_addr\_LSB

Table 15. RAM addr LSB - RAM address LSB register (address 1Bh) bit description

Bit	Symbol	Description
7 to 0	RA[7:0]	RAM address, LSB (1st to 8th bit)

#### 8.5.3 Register RAM\_wrt\_cmd

#### Table 16. RAM\_wrt\_cmd - RAM write command register (address 1Ch) bit description

Bit	Symbol	Description	
7 to 0	-	data to be written into RAM	

#### 8.5.4 Register RAM\_rd\_cmd

### Table 17. RAM\_rd\_cmd - RAM read command register (address 1Dh) bit description

Bit	Symbol	Description	
7 to 0	-	data to be read from RAM	

### Integrated RTC, TCXO and quartz crystal

#### 8.5.5 Operation examples

#### 8.5.5.1 Writing to the RAM

- 1. Set RAM address:
  - Select register RAM\_addr\_MSB (send address 1Ah).
  - Set value for bit RA8 (data byte of register 1Ah).
     Note: register address will be incremented automatically to 1Bh.
  - Set value for array RA[7:0] (data byte of register 1Bh).
- 2. Send RAM write command:
  - Select register RAM\_wrt\_cmd (send address 1Ch).
- 3. Write data into the RAM:
  - Write n data byte into RAM.

For details, see Figure 44 on page 61.

#### 8.5.5.2 Reading from the RAM

- 1. Set RAM address:
  - Select register RAM\_addr\_MSB (send address 1Ah).
  - Set value for bit RA8 (data byte of register 1Ah).
     Note: register address will be incremented automatically to 1Bh.
  - Set value for array RA[7:0] (data byte of register 1Bh).
- 2. Send RAM read command:
  - Select register RAM rd cmd (send address 1Dh).
- 3. Read from the RAM:
  - Read n data byte from the RAM.

For details, see Figure 45 on page 62.

### Integrated RTC, TCXO and quartz crystal

### 8.6 Power management functions

The PCF2127AT has two power supply pins and one power output pin:

- V<sub>DD</sub> the main power supply input pin
- V<sub>BAT</sub> the battery backup input pin
- BBS battery backed output voltage pin (equal to the internal power supply)

The PCF2127AT has three power management functions implemented:

- Battery switch-over function
- · Battery low detection function
- Extra power fail detection function

The power management functions are controlled by the control bits PWRMNG[2:0] in register Control\_3:

Table 18. Power management control bit description

PWRMNG[2:0]		Function
000	[1]	battery switch-over function is enabled in standard mode;
		battery low detection function is enabled;
		extra power fail detection function is enabled
001		battery switch-over function is enabled in standard mode;
		battery low detection function is disabled;
		extra power fail detection function is enabled
010		battery switch-over function is enabled in standard mode;
		battery low detection function is disabled;
		extra power fail detection function is disabled
011		battery switch-over function is enabled in direct switching mode;
		battery low detection function is enabled;
		extra power fail detection function is enabled
100		battery switch-over function is enabled in direct switching mode;
		battery low detection function is disabled;
		extra power fail detection function is enabled
101		battery switch-over function is enabled in direct switching mode;
		battery low detection function is disabled;
		extra power fail detection function is disabled
110	[2]	battery switch-over function is disabled - only one power supply (V <sub>DD</sub> );
		battery low detection function is disabled;
		extra power fail detection function is enabled
111	[2]	battery switch-over function is disabled - only one power supply (V <sub>DD</sub> );
		battery low detection function is disabled;
		extra power fail detection function is disabled

<sup>[1]</sup> Default value.

<sup>[2]</sup> When the battery switch-over function is disabled, the PCF2127AT works only with the power supply  $V_{DD}$ ;  $V_{BAT}$  must be put to ground and the battery low detection function is disabled.

#### Integrated RTC, TCXO and quartz crystal

#### 8.6.1 Battery switch-over function

The PCF2127AT has a backup battery switch-over circuit which monitors the main power supply  $V_{DD}$ . When a power failure condition is detected, it automatically switches to the backup battery.

One of two operation modes can be selected:

- Standard mode: the power failure condition happens when:
   V<sub>DD</sub> < V<sub>BAT</sub> AND V<sub>DD</sub> < V<sub>th(sw)bat</sub>
   V<sub>th(sw)bat</sub> is the battery switch threshold voltage. Typical value is 2.5 V. The battery switch-over in standard mode works only for V<sub>DD</sub> > 2.5 V.
- Direct switching mode: the power failure condition happens when V<sub>DD</sub> < V<sub>BAT</sub>.
   Direct switching from V<sub>DD</sub> to V<sub>BAT</sub> without requiring V<sub>DD</sub> to drop below V<sub>th(sw)bat</sub>

When a power failure condition occurs and the power supply switches to the battery, the following sequence occurs:

- 1. The battery switch flag BF (register Control\_3) is set logic 1.
- 2. An interrupt is generated if the control bit BIE (register Control\_3) is enabled (see Section 8.13.7).
- 3. If the control bit BTSE (register Control\_3) is logic 1, the timestamp registers store the time and date when the battery switch occurred (see Section 8.12.4).
- The battery switch flag BF is cleared by command; it must be cleared to clear the interrupt.

The interface is disabled in battery backup operation:

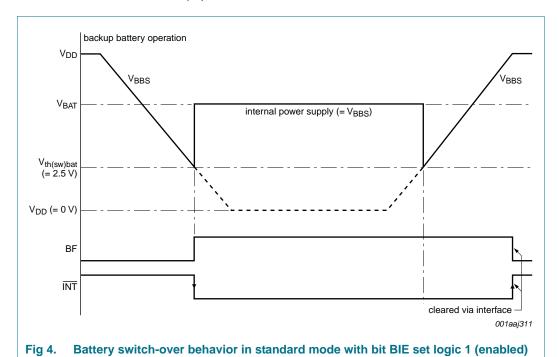
- Interface inputs are not recognized, preventing extraneous data being written to the device
- · Interface outputs are high-impedance

### Integrated RTC, TCXO and quartz crystal

### 8.6.1.1 Standard mode

If  $V_{DD} > V_{BAT}$  OR  $V_{DD} > V_{th(sw)bat}$ , the internal power supply is  $V_{DD}$ .

If  $V_{DD} < V_{BAT}$  AND  $V_{DD} < V_{th(sw)bat}$ , the internal power supply is  $V_{BAT}$ .

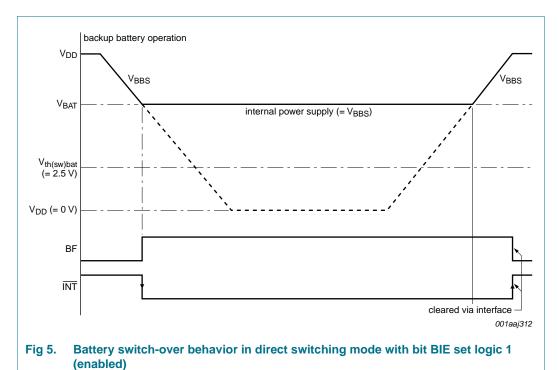


### Integrated RTC, TCXO and quartz crystal

#### 8.6.1.2 Direct switching mode

If  $V_{DD} > V_{BAT}$ , the internal power supply is  $V_{DD}$ .

If  $V_{DD} < V_{BAT}$ , the internal power supply is  $V_{BAT}$ .



The direct switching mode is useful in systems where  $V_{DD}$  is higher than  $V_{BAT}$  at all times. This mode is not recommended if the  $V_{DD}$  and  $V_{BAT}$  values are similar (for example,  $V_{DD}$  = 3.3 V,  $V_{BAT} \ge 3.0$  V). In direct switching mode, the power consumption is reduced compared to the standard mode because the monitoring of  $V_{DD}$  and  $V_{th(sw)bat}$  is not performed.

### 8.6.1.3 Battery switch-over disabled: only one power supply (V<sub>DD</sub>)

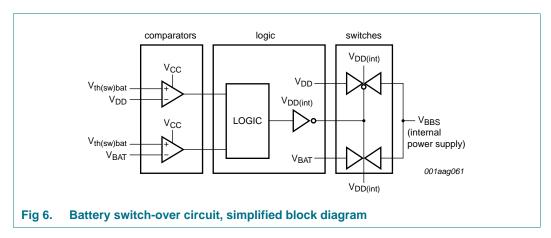
When the battery switch-over function is disabled:

- The power supply is applied on the V<sub>DD</sub> pin
- The V<sub>BAT</sub> pin must be connected to ground
- The internal power supply, available at the output pin BBS, is equal to V<sub>DD</sub>
- The battery flag (BF) is always logic 0

### Integrated RTC, TCXO and quartz crystal

### 8.6.1.4 Battery switch-over architecture

The architecture of the battery switch-over circuit is shown in Figure 6.



The internal power supply (available on pin BBS) is equal to  $V_{DD}$  or  $V_{BAT}$ . It has to be assured that there are decoupling capacitors on the pins  $V_{DD}$ ,  $V_{BAT}$ , and BBS.

### 8.6.2 Battery backup supply

The  $V_{BBS}$  voltage on the output pin BBS is equal to the internal power supply, depending on the selected battery switch-over function mode:

Table 19. Output pin BBS

Battery switch-over function mode	Conditions	V <sub>BBS</sub> equals
standard	$V_{DD} > V_{BAT}$ or $V_{DD} > V_{th(sw)bat}$	$V_{DD}$
	$V_{DD} < V_{BAT}$ and $V_{DD} < V_{th(sw)bat}$	$V_{BAT}$
direct switching	$V_{DD} > V_{BAT}$	$V_{DD}$
	$V_{DD} < V_{BAT}$	$V_{BAT}$
disabled	only V <sub>DD</sub> available, V <sub>BAT</sub> must be put to ground	$V_{DD}$

The output pin BBS can be used as a supply for external devices with battery backup needs, such as SRAM (see Ref. 3 "AN10857"). For this case, Figure 7 shows the typical driving capability when  $V_{BBS}$  is driven from  $V_{DD}$ .

#### Integrated RTC, TCXO and quartz crystal

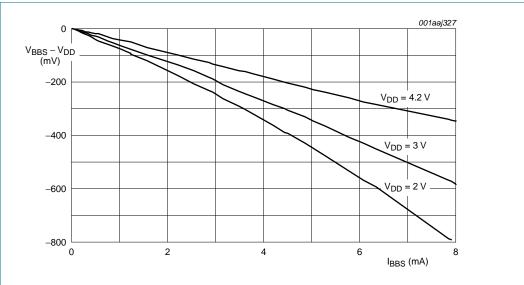


Fig 7. Typical driving capability of V<sub>BBS</sub>: (V<sub>BBS</sub> – V<sub>DD</sub>) with respect to the output load current I<sub>BBS</sub>

#### 8.6.3 Battery low detection function

The PCF2127AT has a battery low detection circuit which monitors the status of the battery  $V_{\text{BAT}}$ .

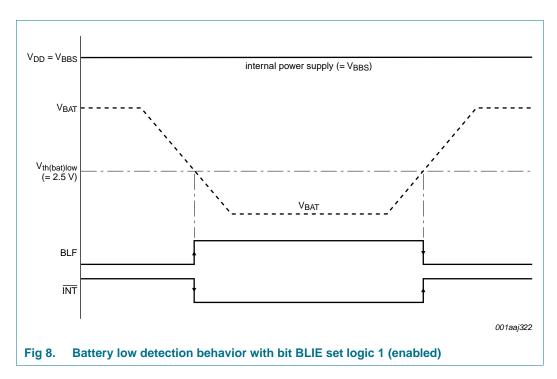
When  $V_{BAT}$  drops below the threshold value  $V_{th(bat)low}$  (typically 2.5 V), the BLF flag (register Control\_3) is set to indicate that the battery is low and that it must be replaced. Monitoring of the battery voltage also occurs during battery operation.

An unreliable battery cannot prevent that the supply voltage drops below  $V_{\text{low}}$  (typical 1.2 V) and with that the data integrity gets lost.

When  $V_{BAT}$  drops below the threshold value  $V_{th(bat)low}$ , the following sequence occurs (see Figure 8):

- 1. The battery low flag BLF is set logic 1.
- 2. An interrupt is generated if the control bit BLIE (register Control\_3) is enabled (see Section 8.13.8).
- 3. The flag BLF remains logic 1 until the battery is replaced. BLF cannot be cleared by command. It is cleared automatically by the battery low detection circuit when the battery is replaced.

#### Integrated RTC, TCXO and quartz crystal

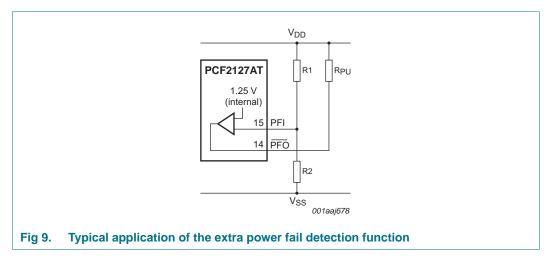


### 8.6.4 Extra power fail detection function

The PCF2127AT has an extra power fail detection circuit which compares the voltage at the power fail input pin PFI to an internal reference voltage equal to 1.25 V.

If  $V_{PFI}$  < 1.25 V, the power fail output  $\overline{PFO}$  is driven LOW.  $\overline{PFO}$  is an open-drain, active LOW output which requires an external pull-up resistor in any application.

The extra power fail detection function is typically used as a low voltage detection for the main power supply V<sub>DD</sub> (see Figure 9).



Usually R1 and R2 should be chosen such that the voltage at pin PFI

- is higher than 1.25 V at start-up
- falls below 1.25 V when V<sub>DD</sub> falls below a desired threshold voltage, V<sub>th(uvp)</sub>, defined by <u>Equation 1</u>:

PCF2127AT

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#### Integrated RTC, TCXO and quartz crystal

$$V_{th(uvp)} = \left(\frac{R_1}{R_2} + I\right) \times 1.25V \tag{1}$$

 $V_{th(uvp)}$  value is usually set to a value that there are several milliseconds before  $V_{DD}$  falls below the minimum operating voltage of the system, in order to allow the microcontroller to perform early backup operations.

If the extra power fail detection function is not used, pin PFI must be connected to  $V_{SS}$  and pin  $\overline{PFO}$  must be left open circuit.

### 8.6.4.1 Extra power fail detection when the battery switch over function is enabled

- When the power switches to the backup battery supply V<sub>BAT</sub>, the power fail comparator is switched off and the power fail output at pin PFO goes (or remains) LOW
- When the power switches back to the main  $V_{DD}$ , the pin  $\overline{PFO}$  is not driven LOW anymore and is pulled HIGH through the external pull-up resistance for a certain time ( $t_{rec} = 15.63$  ms to 31.25 ms) and then the power fail comparator is enabled again

For illustration, see Figure 10 and Figure 11.

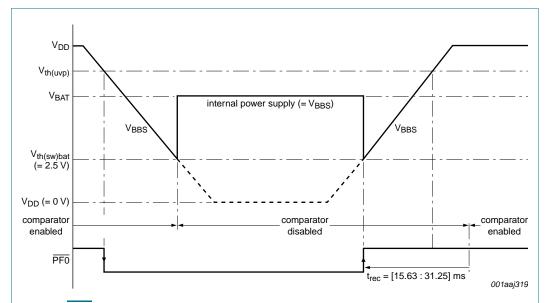


Fig 10.  $\overline{PFO}$  signal behavior when battery switch-over is enabled in standard mode and  $V_{th(uvp)} > (V_{BAT}, V_{th(sw)bat})$ 

### Integrated RTC, TCXO and quartz crystal

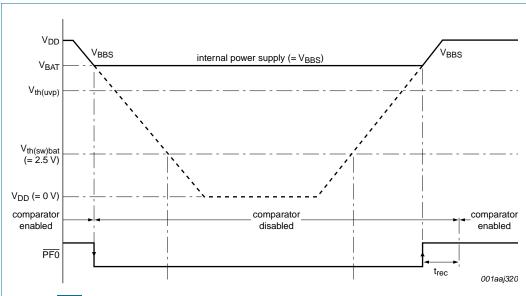
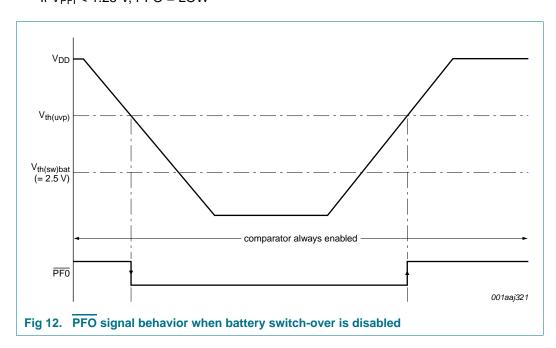


Fig 11.  $\overline{\text{PFO}}$  signal behavior when battery switch-over is enabled in direct switching mode and  $V_{\text{th(uvp)}} < V_{\text{BAT}}$ 

### 8.6.4.2 Extra power fail detection when the battery switch-over function is disabled

If the battery switch-over function is disabled and the power fail comparator is enabled, the power fail output at pin  $\overline{PFO}$  depends only on the result of the comparison between  $V_{PFI}$  and 1.25 V:

- If  $V_{PFI} > 1.25 \text{ V}$ ,  $\overline{PFO} = \text{HIGH}$  (through the external pull-up resistor)
- If  $V_{PFI} < 1.25 \text{ V}$ ,  $\overline{PFO} = LOW$



#### Integrated RTC, TCXO and quartz crystal

### 8.7 Oscillator stop detection function

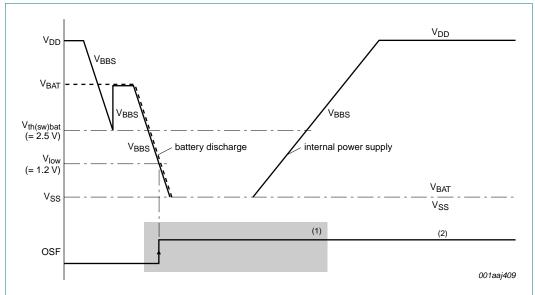
The PCF2127AT has an on-chip oscillator detection circuit which monitors the status of the oscillation: whenever the oscillation stops, a reset occurs and the oscillator stop flag OSF (in register Seconds) is set logic 1.

#### • Power-on:

- a. The oscillator is not running, the chip is in reset (pin RST is LOW and flag OSF is logic 1).
- b. When the oscillator starts running and is stable after power-on, the chip exits from reset (pin RST is HIGH).
- c. The flag OSF is still logic 1 and can be cleared (OSF set logic 0) by command.

### • Power supply failure:

- a. When the power supply of the chip ( $V_{BBS}$ , see <u>Section 8.6.2</u>) drops below a certain value ( $V_{low}$ ), typically 1.2 V, the oscillator stops running and a reset occurs.
- b. When the power supply returns to normal operation, the oscillator starts running again, the chip exits from reset.
- c. The flag OSF is still logic 1 and can be cleared (OSF set logic 0) by command.



- (1) Theoretical state of the signals since there is no power.
- (2) The oscillator stop flag (OSF), set logic 1, indicates that the oscillation has stopped and a reset has occurred since the flag was last cleared (OSF set logic 0). In this case, the integrity of the clock information is not guaranteed. The OSF flag is cleared by command.

Fig 13. Power failure event due to battery discharge: reset occurs

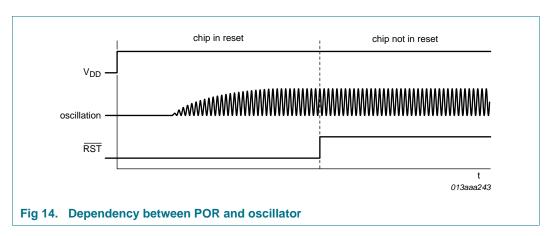
#### Integrated RTC, TCXO and quartz crystal

#### 8.8 Reset function

The PCF2127AT has a Power-On Reset (POR) and a Power-On Reset Override (PORO) function implemented.

### 8.8.1 Power-On Reset (POR)

The POR is active whenever the oscillator is stopped. The oscillator is also considered to be stopped during the time between power-on and stable crystal resonance (see Figure 14). This time may be in the range of 200 ms to 2 s depending on temperature and supply voltage. Whenever an internal reset occurs, the oscillator stop flag is set (OSF set logic 1).



After POR, the following mode is entered:

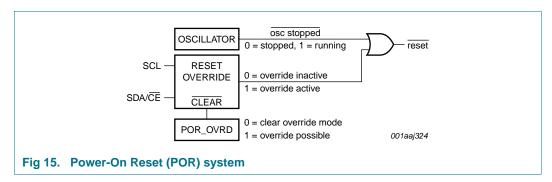
- 32.768 kHz CLKOUT active
- Power-On Reset Override (PORO) available to be set
- 24 hour mode is selected
- Battery switch-over is enabled
- Battery low detection is enabled
- Extra power fail detection is enabled

The register values after power-on are shown in Table 5.

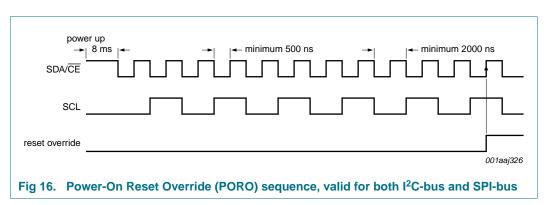
#### 8.8.2 Power-On Reset Override (PORO)

The POR duration is directly related to the crystal oscillator start-up time. Due to the long start-up times experienced by these types of circuits, a mechanism has been built in to disable the POR and therefore speed up the on-board test of the device.

#### Integrated RTC, TCXO and quartz crystal



The setting of the PORO mode requires that POR\_OVRD in register Control\_1 is set logic 1 and that the signals at the interface pins SDA/CE and SCL are toggled as illustrated in Figure 16. All timings shown are required minimum.



Once the override mode is entered, the device is immediately released from the reset state and the set-up operation can commence.

The PORO mode is cleared by writing logic 0 to POR\_OVRD. POR\_OVRD must be logic 1 before a re-entry into the override mode is possible. Setting POR\_OVRD logic 0 during normal operation has no effect except to prevent accidental entry into the PORO mode.

### Integrated RTC, TCXO and quartz crystal

### 8.9 Time and date function

Most of these registers are coded in the Binary Coded Decimal (BCD) format.

### 8.9.1 Register Seconds

Table 20. Seconds - seconds and clock integrity register (address 03h) bit description

Bit	Symbol	Value	Place value	Description
7	OSF	0	-	clock integrity is guaranteed
		1[1]	-	clock integrity is not guaranteed: oscillator has stopped and chip reset has occurred since flag was last cleared
6 to 4	SECONDS	NDS 0 to 5		actual seconds coded in BCD format
3 to 0		0 to 9	unit place	

<sup>[1]</sup> Start-up value.

Table 21. Seconds coded in BCD format

Seconds value in	Upper-digit (ten's place)			Digit (unit place)			
decimal	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
00	0	0	0	0	0	0	0
01	0	0	0	0	0	0	1
02	0	0	0	0	0	1	0
:	:	:	:	:	:	:	
09	0	0	0	1	0	0	1
10	0	0	1	0	0	0	0
:	:	:	:	:	:	:	
58	1	0	1	1	0	0	0
59	1	0	1	1	0	0	1

### 8.9.2 Register Minutes

Table 22. Minutes - minutes register (address 04h) bit description

Bit	Symbol	Value	Place value	Description
7	-	-	-	unused
6 to 4	MINUTES	0 to 5	ten's place	actual minutes coded in BCD format
3 to 0		0 to 9	unit place	

### Integrated RTC, TCXO and quartz crystal

### 8.9.3 Register Hours

Table 23. Hours - hours register (address 05h) bit description

		_			
Bit	Symbol	Value	Place value	Description	
7 to 6	-	-	-	unused	
12 ho	ur mode[1]				
5	AMPM	0	-	indicates AM	
		1	-	indicates PM	
4	HOURS	0 to 1	ten's place	actual hours coded in BCD format when in	
3 to 0		0 to 9	unit place	12 hour mode	
24 hour mode[1]					
5 to 4 HOURS		0 to 2	ten's place	actual hours coded in BCD format when in	
3 to 0		0 to 9	unit place	24 hour mode	

<sup>[1]</sup> Hour mode is set by the bit 12\_24 in register Control\_1.

### 8.9.4 Register Days

Table 24. Days - days register (address 06h) bit description

Bit	Symbol	Value	Place value	Description
7 to 6	-	-	-	unused
5 to 4	DAYS[1]	0 to 3	ten's place	actual day coded in BCD format
3 to 0		0 to 9	unit place	

<sup>[1]</sup> If the year counter contains a value which is exactly divisible by 4, including the year 00, the RTC compensates for leap years by adding a 29<sup>th</sup> day to February.

### 8.9.5 Register Weekdays

Table 25. Weekdays - weekdays register (address 07h) bit description

Bit	Symbol	Value	Description
7 to 3	-	-	unused
2 to 0	WEEKDAYS	0 to 6	actual weekday value, see Table 26

Although the association of the weekdays counter to the actual weekday is arbitrary, the PCF2127AT will assume that Sunday is 000 and Monday is 001 for the purposes of determining the increment for calendar weeks.

Table 26. Weekday assignments

Day[1]	Bit				
	2	1	0		
Sunday	0	0	0		
Monday	0	0	1		
Tuesday	0	1	0		
Wednesday	0	1	1		
Thursday	1	0	0		
Friday	1	0	1		
Saturday	1	1	0		

<sup>[1]</sup> These bits may be reassigned by the user.

PCF2127AT

### Integrated RTC, TCXO and quartz crystal

### 8.9.6 Register Months

Table 27. Months - months register (address 08h) bit description

Bit	Symbol	Value	Place value	Description
7 to 5	-	-	-	unused
4	MONTHS	0 to 1	ten's place	actual month coded in BCD format, see
3 to 0		0 to 9	unit place	Table 28

Table 28. Month assignments in BCD format

Month	Upper-digit (ten's place)	Digit (unit place)				
	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
January	0	0	0	0	1	
February	0	0	0	1	0	
March	0	0	0	1	1	
April	0	0	1	0	0	
May	0	0	1	0	1	
June	0	0	1	1	0	
July	0	0	1	1	1	
August	0	1	0	0	0	
September	0	1	0	0	1	
October	1	0	0	0	0	
November	1	0	0	0	1	
December	1	0	0	1	0	

### 8.9.7 Register Years

Table 29. Years - years register (address 09h) bit description

Bit	Symbol	Value	Place value	Description
7 to 4	YEARS	0 to 9	ten's place	actual year coded in BCD format
3 to 0	_	0 to 9	unit place	-

### 8.9.8 Setting and reading the time

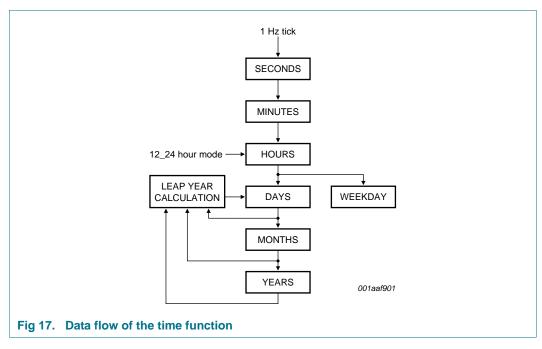
Figure 17 shows the data flow and data dependencies starting from the 1 Hz clock tick.

During read/write operations, the time counting circuits (memory locations 03h through 09h) are blocked.

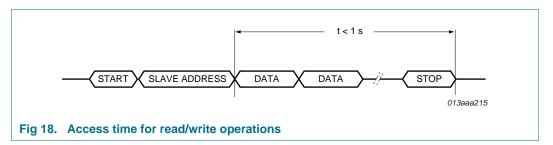
This prevents

- Faulty reading of the clock and calendar during a carry condition
- Incrementing the time registers during the read cycle

#### Integrated RTC, TCXO and quartz crystal



After this read/write access is completed, the time circuit is released again. Any pending request to increment the time counters that occurred during the read/write access is serviced. A maximum of 1 request can be stored; therefore, all accesses must be completed within 1 second (see <a href="Figure 18">Figure 18</a>).



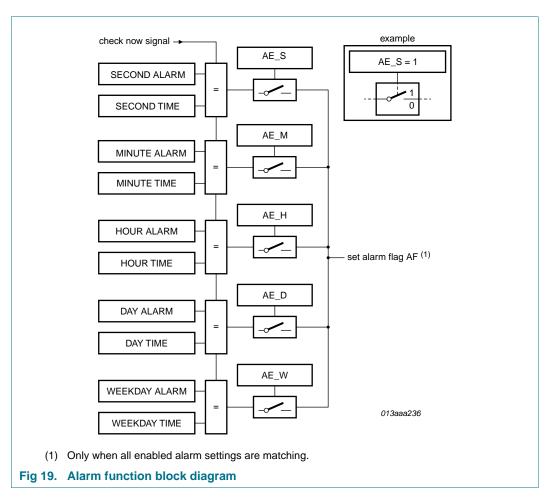
As a consequence of this method, it is very important to make a read or write access in one go, that is, setting or reading seconds through to years should be made in one single access. Failing to comply with this method could result in the time becoming corrupted.

As an example, if the time (seconds through to hours) is set in one access and then in a second access the date is set, it is possible that the time may increment between the two accesses. A similar problem exists when reading. A roll-over may occur between reads thus giving the minutes from one moment and the hours from the next. Therefore it is advised to read all time and date registers in one access.

### Integrated RTC, TCXO and quartz crystal

### 8.10 Alarm function

When one or more of the alarm bit fields are loaded with a valid second, minute, hour, day, or weekday and its corresponding alarm enable bit (AE\_x) is logic 0, then that information is compared with the actual second, minute, hour, day, and weekday (see Figure 19).



The generation of interrupts from the alarm function is described in <u>Section 8.13.5</u>.

### 8.10.1 Register Second\_alarm

Table 30. Second\_alarm - second alarm register (address 0Ah) bit description

Bit	Symbol	Value	Place value	Description
7	AE_S	0	-	second alarm is enabled
		1[1]	-	second alarm is disabled
6 to 4	SECOND_ALARM	0 to 5	ten's place	second alarm information coded in BCD
3 to 0		0 to 9	unit place	format

<sup>[1]</sup> Default value.

### Integrated RTC, TCXO and quartz crystal

### 8.10.2 Register Minute\_alarm

Table 31. Minute\_alarm - minute alarm register (address 0Bh) bit description

Bit	Symbol	Value	Place value	Description
7	AE_M	0	-	minute alarm is enabled
		1[1]	-	minute alarm is disabled
6 to 4	MINUTE_ALARM	0 to 5	ten's place	minute alarm information coded in BCD
3 to 0		0 to 9	unit place	format

<sup>[1]</sup> Default value.

### 8.10.3 Register Hour\_alarm

Table 32. Hour\_alarm - hour alarm register (address 0Ch) bit description

				•	
Bit	Symbol	Value	Place value	Description	
7	AE_H	0	-	hour alarm is enabled	
		1[1]	-	hour alarm is disabled	
6	-	-	-	unused	
12 hour mode <sup>[2]</sup>					
5	AMPM	0	-	indicates AM	
		1	-	indicates PM	
4	HOUR_ALARM	0 to 1	ten's place	hour alarm information coded in BCD	
3 to 0		0 to 9	unit place	format when in 12 hour mode	
24 hour mode <sup>[2]</sup>					
5 to 4	HOUR_ALARM	0 to 2	ten's place	hour alarm information coded in BCD	
3 to 0	)	0 to 9	unit place	format when in 24 hour mode	

<sup>[1]</sup> Default value.

### 8.10.4 Register Day\_alarm

Table 33. Day\_alarm - day alarm register (address 0Dh) bit description

Bit	Symbol	Value	Place value	Description
7	AE_D	0	-	day alarm is enabled
		1[1]	-	day alarm is disabled
6	-	-	-	unused
5 to 4	DAY_ALARM	0 to 3	ten's place	day alarm information coded in BCD
3 to 0		0 to 9	unit place	format

<sup>[1]</sup> Default value.

<sup>[2]</sup> Hour mode is set by the bit 12\_24 in register Control\_1.

### Integrated RTC, TCXO and quartz crystal

### 8.10.5 Register Weekday\_alarm

Table 34. Weekday\_alarm - weekday alarm register (address 0Eh) bit description

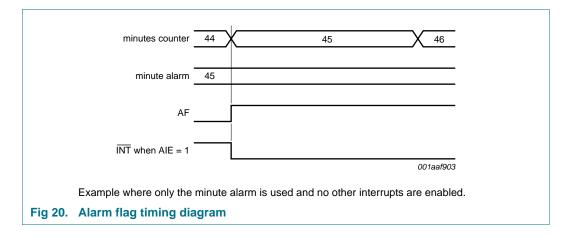
	<u> </u>		
Bit	Symbol	Value	Description
7	AE_W	0	weekday alarm is enabled
		1[1]	weekday alarm is disabled
6 to 3	-	-	unused
2 to 0	WEEKDAY_ALARM	0 to 6	weekday alarm information

<sup>[1]</sup> Default value.

#### 8.10.6 Alarm flag

When all enabled comparisons first match, the alarm flag AF (register Control\_2) is set. AF will remain set until cleared by command. Once AF has been cleared, it will only be set again when the time increments to match the alarm condition once more. For clearing the flags, see <a href="Section 8.11.6">Section 8.11.6</a>

Alarm registers which have their alarm enable bit AE\_x at logic 1 are ignored.



### Integrated RTC, TCXO and quartz crystal

### 8.11 Timer functions

The PCF2127AT has two different timer functions, a watchdog timer and a countdown timer. The timers can be selected by using the control bits WD\_CD[1:0] in the register Watchdg\_tim\_ctl.

- The watchdog timer has four selectable source clocks. It can, for example, be used to
  detect a microprocessor with interrupt and reset capability which is out of control (see
  Section 8.11.3)
- The countdown timer has four selectable source clocks allowing for countdown periods from less than 1 ms to more than 4 hours (see Section 8.11.4)

To control the timer functions and timer output, the registers Control\_2, Watchdg\_tim\_ctl, and Watchdg\_tim\_val are used.

### 8.11.1 Register Watchdg\_tim\_ctl

Table 35. Watchdg\_tim\_ctl - watchdog timer control register (address 10h) bit description

Bit	Symbol	Value	Description
7 to 6	WD_CD[1:0]	00[1]	watchdog timer disabled; countdown timer disabled
		01	watchdog timer disabled; countdown timer enabled
			if CDTIE is set logic 1, the interrupt pin INT is activated when the countdown timed out
	10	watchdog timer enabled; the interrupt pin INT is activated when timed out; countdown timer not available	
		11	watchdog timer enabled; the reset pin $\overline{RST}$ is activated when timed out; countdown timer not available
5	TI_TP	0[1]	the interrupt pin $\overline{\text{INT}}$ is configured to generate a permanent active signal when MSF and/or CDTF is set
		1	the interrupt pin INT is configured to generate a pulsed signal when MSF flag and/or CDTF flag is set (see Figure 25)
4 to 2	-	-	unused
1 to 0	TF[1:0]		timer source clock for watchdog and countdown timer
		00	4.096 kHz
		01	64 Hz
		10	1 Hz
		11 <sup>[1]</sup>	1/ <sub>60</sub> Hz

<sup>[1]</sup> Default value.

#### Integrated RTC, TCXO and quartz crystal

#### 8.11.2 Register Watchdg\_tim\_val

Table 36. Watchdg\_tim\_val - watchdog timer value register (address 11h) bit description

Bit	Symbol	Value	Description
7 to 0	WATCHDG_TIM_VAL[7:0]	00 to FF	countdown period in seconds:
			$CountdownPeriod = \frac{n}{SourceClockFrequency}$
			where n is the countdown value

Table 37. Programmable watchdog or countdown timer

TF[1:0]	Timer source clock frequency	Units	Minimum timer period (n = 1)	Units	Maximum timer period (n = 255)	Units
00	4.096	kHz	244	μS	62.256	ms
01	64	Hz	15.625	ms	3.984	S
10	1	Hz	1	S	255	S
11	1/60	Hz	60	s	15300	s

#### 8.11.3 Watchdog timer function

The watchdog timer function is enabled or disabled by the WD\_CD[1:0] bits of the register Watchdg\_tim\_ctl (see Table 35).

The two bits TF[1:0] in register Watchdg\_tim\_ctl determine one of the four source clock frequencies for the watchdog timer: 4.096 kHz, 64 Hz, 1 Hz, or  $\frac{1}{60}$  Hz (see Table 37).

When the watchdog timer function is enabled, the 8-bit timer in register Watchdg\_tim\_val determines the watchdog timer period (see <u>Table 36</u>).

The watchdog timer counts down from the software programmed 8-bit binary value n in register Watchdg\_tim\_val. When the counter reaches 1, the watchdog timer flag WDTF (register Control\_2) is set logic 1.

In the case that WDTF is logic 1:

- if WD\_CD[1:0] = 10 an interrupt will be generated
- if WD\_CD[1:0] = 11 a reset will be generated

The counter does not automatically reload.

When WD\_CD[1:0] = 10 or WD\_CD[1:0] = 11 and the microcontroller unit (MCU) loads a watchdog timer value n:

- the flag WDTF is reset
- INT or RST is cleared
- the watchdog timer starts again

Loading the counter with 0 will:

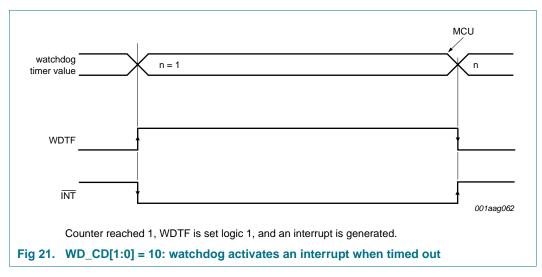
- reset the flag WDTF
- clear INT or RST
- stop the watchdog timer

## Integrated RTC, TCXO and quartz crystal

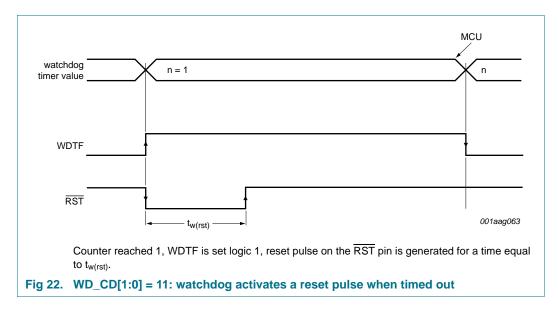
**Remark:** WDTF is read only and cannot be cleared by command. WDTF can be cleared by:

- loading a value in register Watchdg\_tim\_val
- reading of the register Control\_2

Writing a logic 0 or logic 1 to WDTF has no effect.



- When the watchdog timer counter reaches 1, the watchdog timer flag WDTF is set logic 1
- When a minute or second interrupt occurs, the minute/second flag MSF is set logic 1 (see <u>Section 8.13.1</u>)



#### Integrated RTC, TCXO and quartz crystal

Table 38. Specification of tw(rst)

WD_CD[1:0]	TF[1:0]	t <sub>w(rst)</sub>
11	00	244 μs
	01	15.625 ms
	10	15.625 ms
	11	15.625 ms

#### 8.11.4 Countdown timer function

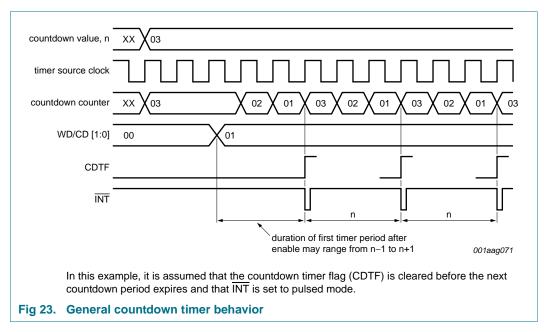
The countdown timer function is controlled by the WD\_CD[1:0] bits in register Watchdg\_tim\_ctl (see Table 35).

The timer counts down from the software programmed 8 bit binary value n in register Watchdg\_tim\_val. When the counter reaches 1

- the countdown timer flag CDTF is set
- · the counter automatically reloads
- and the next time period starts

Loading the counter with 0 effectively stops the timer.

Reading the timer returns the actual value of the countdown counter.



If a new value of n is written before the end of the actual timer period, this value takes immediate effect. It is not recommended to change n without first disabling the counter by setting WD\_CD[1:0] = 00. The update of n is asynchronous to the timer clock. Therefore changing it on the fly could result in a corrupted value loaded into the countdown counter. This can result in an undetermined countdown period for the first period. The countdown value n will, however, be correctly stored and correctly loaded on subsequent timer periods.

#### Integrated RTC, TCXO and quartz crystal

When the countdown timer flag CDTF is set, an interrupt signal on INT will be generated if this mode is enabled. See <u>Section 8.13.2</u> for details on how the interrupt can be controlled.

When starting the countdown timer for the first time, only the first period will not have a fixed duration. The amount of inaccuracy for the first timer period will depend on the chosen source clock, see Table 39.

Table 39. First period delay for timer counter

Timer source clock	Minimum timer period	Maximum timer period
4.096 kHz	n	n + 1
64 Hz	n	n + 1
1 Hz	(n – 1) + ½ Hz	n + ½ Hz
1/ <sub>60</sub> Hz	(n – 1) + ½ Hz	n + ½ Hz

At the end of every countdown, the timer sets the countdown timer flag (CDTF). CDTF may only be cleared by software. The asserted CDTF can be used to generate an interrupt (INT). The interrupt may be generated as a pulsed signal every countdown period or as a permanently active signal which follows the condition of CDTF. TI\_TP is used to control this mode selection. The interrupt output may be disabled with the CDTIE bit, see Table 7.

When reading the timer, the actual countdown value is returned and **not** the initial value n. Since it is not possible to freeze the countdown timer counter during read back, it is recommended to read the register twice and check for consistent results.

## 8.11.5 Pre-defined timers: second and minute interrupt

PCF2127AT has two pre-defined timers which are used to generate an interrupt either once per second or once per minute. The pulse generator for the minute or second interrupt operates from an internal 64 Hz clock. It is independent of the watchdog or countdown timers. Each of these timers can be enabled by the bits SI (second interrupt) and MI (minute interrupt) in register Control\_1.

#### 8.11.6 Clearing flags

The flags MSF, CDTF, AF and TSFx can be cleared by command. To prevent one flag being overwritten while clearing another, a logic AND is performed during the write access. A flag is cleared by writing logic 0 while a flag is not cleared by writing logic1. Writing logic1 will result in the flag value remaining unchanged.

Four examples are given for clearing the flags. Clearing the flags is made by a write command:

- Bits labeled with must be written with their previous values
- WDTF is read only and has to be written with logic 0

Repeatedly rewriting these bits has no influence on the functional behavior.

Table 40. Flag location in register Control\_2

Register	Bit							
	7	6	5	4	3	2	1	0
Control_2	MSF	WDTF	TSF2	AF	CDTF	-	-	-

PCF2127AT

## Integrated RTC, TCXO and quartz crystal

Table 41. Example values in register Control\_2

Register	Bit							
	7	6	5	4	3	2	1	0
Control_2	1	0	1	1	1	0	0	0

The following tables show what instruction must be sent to clear the appropriate flag.

Table 42. Example to clear only CDTF (bit 3) in register Control\_2

Register	Bit	lit						
	7	6	5	4	3	2	1	0
Control_2	1	0	1	1	0	<u>-[1]</u>	<u>-[1]</u>	<u>-[1]</u>

<sup>[1]</sup> The bits labeled as - have to be rewritten with the previous values.

Table 43. Example to clear only AF (bit 4) in register Control\_2

Register	Bit	3it							
	7	6	5	4	3	2	1	0	
Control_2	1	0	1	0	1	0[1]	0[1]	0[1]	

<sup>[1]</sup> The bits labeled as - have to be rewritten with the previous values.

Table 44. Example to clear only MSF (bit 7) in register Control\_2

Register	Bit	Sit							
	7	6	5	4	3	2	1	0	
Control_2	0	0	1	1	1	0[1]	0[1]	0[1]	

<sup>[1]</sup> The bits labeled as - have to be rewritten with the previous values.

Table 45. Example to clear both CDTF and MSF in register Control\_2

Register	Bit	3it							
	7	6	5	4	3	2	1	0	
Control_2	0	0	1	1	0	0[1]	O[1]	0[1]	

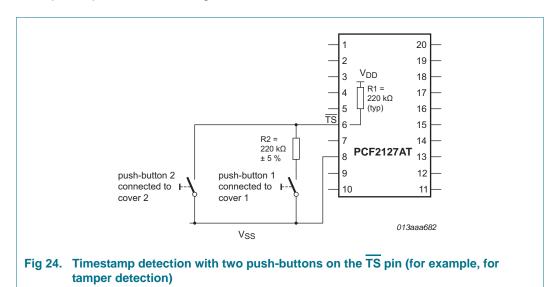
<sup>[1]</sup> The bits labeled as - have to be rewritten with the previous values.

#### Integrated RTC, TCXO and quartz crystal

## 8.12 Timestamp function

The PCF2127AT has an active LOW timestamp input pin  $\overline{TS}$ , internally pulled with an on-chip pull-up resistor to the internal power supply of the device. It also has a timestamp detection circuit which can detect two different events:

- 1. Input on pin  $\overline{TS}$  is driven to an intermediate level between power supply and ground.
- 2. Input on pin TS is driven to ground.



The timestamp function is enabled by default after power-on and it can be switched off by setting the control bit TSOFF (register Timestp\_ctl).

A most common application of the timestamp function is described in Ref. 3 "AN10857".

See Section 8.13.6 for a description of interrupt generation from the timestamp function.

#### 8.12.1 Timestamp flag

- 1. When the  $\overline{\mathsf{TS}}$  input pin is driven to an intermediate level between the power supply and ground, then the following sequence occurs:
  - a. The actual date and time are stored in the timestamp registers.
  - b. The timestamp flag TSF1 (register Control\_1) is set.
  - c. If the TSIE bit (register Control\_2) is active, an interrupt on the INT pin is generated.

The TSF1 flag can be cleared by command. Clearing the flag will clear the interrupt. Once TSF1 is cleared, it will only be set again when a new negative edge on pin TS is detected.

- 2. When the  $\overline{\mathsf{TS}}$  input pin is driven to ground, the following sequence occurs:
  - a. The actual date and time are stored in the timestamp registers.
  - b. In addition to the TSF1 flag, the TSF2 flag (register Control 2) is set.
  - c. If the TSIE bit is active, an interrupt on the INT pin is generated.

#### Integrated RTC, TCXO and quartz crystal

The TSF1 and TSF2 flags can be cleared by command; clearing both flags will clear the interrupt. Once TSF2 is cleared, it will only be set again when  $\overline{\text{TS}}$  pin is driven to ground once again.

## 8.12.2 Time stamp mode

The timestamp function has two different modes selected by the control bit TSM (timestamp mode) in register Timestp\_ctl:

- If TSM is logic 0 (default): in subsequent trigger events without clearing the timestamp flags, the last timestamp event is stored
- If TSM is logic 1: in subsequent trigger events without clearing the timestamp flags, the first timestamp event is stored

The timestamp function also depends on the control bit BTSE in register Control\_3, see Section 8.12.4.

### 8.12.3 Timestamp registers

#### 8.12.3.1 Register Timestp\_ctl

Table 46. Timestp\_ctl - timestamp control register (address 12h) bit description

Bit	Symbol	Value	Description
7	7 TSM		in subsequent events without clearing the timestamp flags, the last event is stored
			in subsequent events without clearing the timestamp flags, the first event is stored
6	TSOFF	0[1]	timestamp function active
		1	timestamp function disabled
5	-	-	unused
4 to 0	1_O_16_TIMESTP[4:0]		$\frac{1}{16}$ second timestamp information coded in BCD format

<sup>[1]</sup> Default value.

### 8.12.3.2 Register Sec\_timestp

Table 47. Sec\_timestp - second timestamp register (address 13h) bit description

Bit	Symbol	Value	Place value	Description
7	-	-	-	unused
6 to 4	SECOND_TIMESTP	0 to 5	ten's place	second timestamp information coded in
3 to 0		0 to 9	unit place	BCD format

## 8.12.3.3 Register Min\_timestp

Table 48. Min\_timestp - minute timestamp register (address 14h) bit description

Bit	Symbol	Value	Place value	Description
7	-	-	-	unused
6 to 4	MINUTE_TIMESTP	0 to 5	ten's place	minute timestamp information coded in
3 to 0		0 to 9	unit place	BCD format

## Integrated RTC, TCXO and quartz crystal

### 8.12.3.4 Register Hour\_timestp

Table 49. Hour\_timestp - hour timestamp register (address 15h) bit description

Bit	Symbol	Value	Place value	Description
7 to 6	-	-	-	unused
12 ho	ur mode[1]			
5	AMPM	0	-	indicates AM
		1	-	indicates PM
4	HOUR_TIMESTP	0 to 1	ten's place	hour timestamp information coded in BCD
3 to 0		0 to 9	unit place	format when in 12 hour mode
24 hour mode <sup>[1]</sup>				
5 to 4 HOUR_TIMESTP		0 to 2	ten's place	hour timestamp information coded in BCD
3 to 0		0 to 9	unit place	format when in 24 hour mode

<sup>[1]</sup> Hour mode is set by the bit 12\_24 in register Control\_1.

## 8.12.3.5 Register Day\_timestp

Table 50. Day\_timestp - day timestamp register (address 16h) bit description

Bit	Symbol	Value	Place value	Description
7 to 6	-	-	-	unused
5 to 4	DAY_TIMESTP	0 to 3	ten's place	day timestamp information coded in BCD
3 to 0		0 to 9	unit place	format

## 8.12.3.6 Register Mon\_timestp

Table 51. Mon\_timestp - month timestamp register (address 17h) bit description

Bit	Symbol	Value	Place value	Description
7 to 5	-	-	-	unused
4	MONTH_TIMESTP	0 to 1	ten's place	month timestamp information coded in
3 to 0		0 to 9	unit place	BCD format

### 8.12.3.7 Register Year\_timestp

Table 52. Year\_timestp - year timestamp register (address 18h) bit description

Bit	Symbol	Value	Place value	Description
7 to 4	YEAR_TIMESTP	0 to 9	ten's place	year timestamp information coded in BCD
3 to 0		0 to 9	unit place	format

## Integrated RTC, TCXO and quartz crystal

## 8.12.4 Dependency between Battery switch-over and timestamp

The timestamp function depends on the control bit BTSE in register Control\_3:

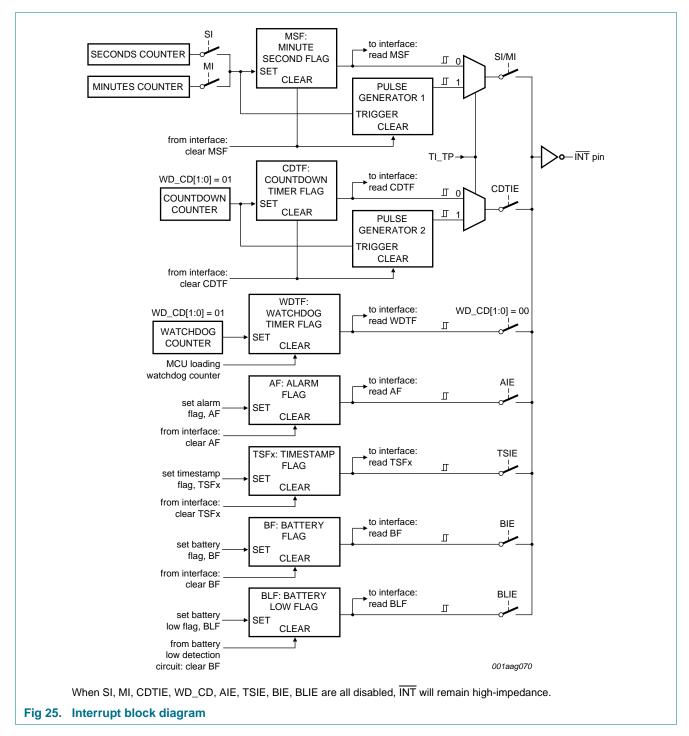
Table 53. Battery switch-over and timestamp

BTSE	BF	Description
0	-	the battery switch-over does not affect the timestamp registers
1		If a battery switch-over event occurs:
	0	the timestamp registers store the time and date when the switch-over occurs; after this event occurred BF is set logic 1
	1	the timestamp registers are not modified; in this condition subsequent battery switch-over events or falling edges on pin $\overline{\text{TS}}$ are not registered

<sup>[1]</sup> Default value.

## Integrated RTC, TCXO and quartz crystal

# 8.13 Interrupt output, INT



PCF2127AT has an interrupt output pin  $\overline{\text{INT}}$  which is open-drain, active LOW. Interrupts may be sourced from different places:

- · second or minute timer
- countdown timer

#### Integrated RTC, TCXO and quartz crystal

- · watchdog timer
- alarm
- timestamp
- battery switch-over
- battery low detection

The control bit TI\_TP (register Watchdg\_tim\_ctl) is used to configure whether the interrupts generated from the second/minute timer (flag MSF in register Control\_2) and the countdown timer (flag CDTF in register Control\_2) are pulsed signals or a permanently active signal. All the other interrupt sources generate a permanently active interrupt signal which follows the status of the corresponding flags. When the interrupt sources are all disabled,  $\overline{\text{INT}}$  remains high-impedance.

- The flags MSF, CDTF, AF, TSFx, and BF can be cleared by command.
- The flag WDTF is read only. How it can be cleared is explained in <u>Section 8.11.6</u>.
- The flag BLF is read only. It is cleared automatically from the battery low detection circuit when the battery is replaced.

#### 8.13.1 Minute and second interrupts

Minute and second interrupts are generated by predefined timers. The timers can be enabled independently from one another by the bits MI and SI in register Control\_1. However, a minute interrupt enabled on top of a second interrupt will not be distinguishable since it will occur at the same time.

The minute/second flag MSF (register Control\_2) is set logic 1 when either the seconds or the minutes counter increments according to the actually enabled interrupt (see <u>Table 54</u>). The MSF flag can be read and cleared by command.

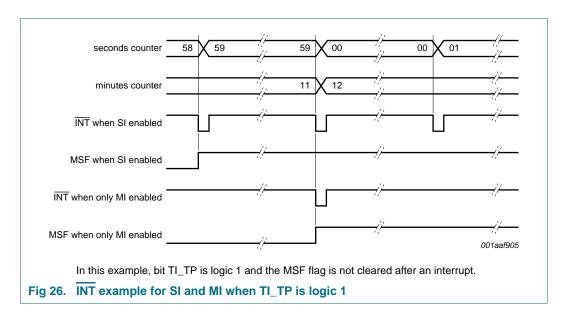
Table 54. Effect of bits MI and SI on pin INT and bit MSF

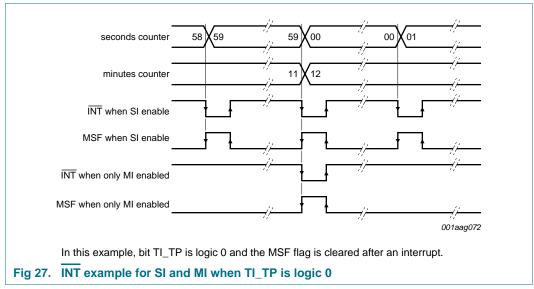
MI	SI	Result on INT	Result on MSF
0	0	no interrupt generated	MSF never set
1	0	an interrupt once per minute	MSF set when minutes counter increments
0	1	an interrupt once per second	MSF set when <b>seconds</b> counter increments
1	1	an interrupt once per second	MSF set when <b>seconds</b> counter increments

#### When MSF is set logic 1:

- If TI TP is logic 1, the interrupt is generated as a pulsed signal.
- If TI\_TP is logic 0, the interrupt is permanently active signal that remains until MSF is cleared.

#### Integrated RTC, TCXO and quartz crystal





The pulse generator for the minute/second interrupt operates from an internal 64 Hz clock and generates a pulse of  $\frac{1}{64}$  seconds in duration.

### 8.13.2 Countdown timer interrupts

The generation of interrupts from the countdown timer is controlled by the CDTIE bit (register Control 2).

The interrupt may be generated as a pulsed signal at every countdown period or as a permanently active signal which follows the status of the countdown timer flag CDTF. Bit TI\_TP is used to control this bit.

## Integrated RTC, TCXO and quartz crystal

# 8.13.3 INT pulse shortening

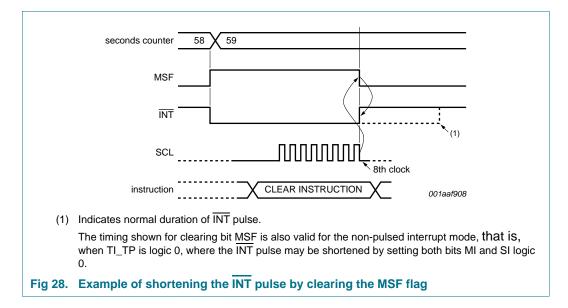
The pulse generator for the countdown timer interrupt also uses an internal clock, but this time it is dependent on the selected source clock for the countdown timer and on the countdown value n. As a consequence, the width of the interrupt pulse varies (see Table 55).

Table 55. INT operation (bit TI\_TP = 1)

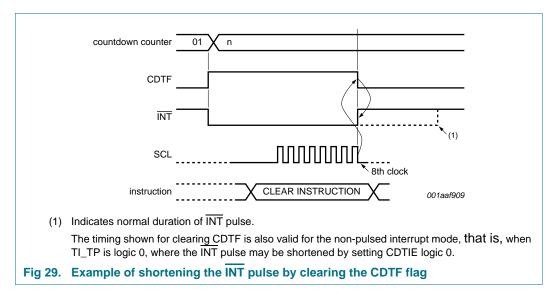
Source clock (Hz)	INT period (s)			
	n = 1 [1]	n > 1		
4096	1/8192	1/4096		
64	<sup>1</sup> / <sub>128</sub>	1/64		
1	1/64	1/64		
1/60	1/64	1/64		

<sup>[1]</sup> n = loaded countdown value. Timer stopped when n = 0.

If the MSF or CDTF flag (register Control\_2) is cleared before the end of the  $\overline{\text{INT}}$  pulse, then the  $\overline{\text{INT}}$  pulse is shortened. This allows the source of a system interrupt to be cleared immediately when it is serviced, that is, the system does not have to wait for the completion of the pulse before continuing, see <a href="Figure 28">Figure 28</a> and <a href="Figure 29">Figure 29</a>. Instructions for clearing bit MSF and bit CDTF can be found in <a href="Section 8.11.6">Section 8.11.6</a>.



#### Integrated RTC, TCXO and quartz crystal



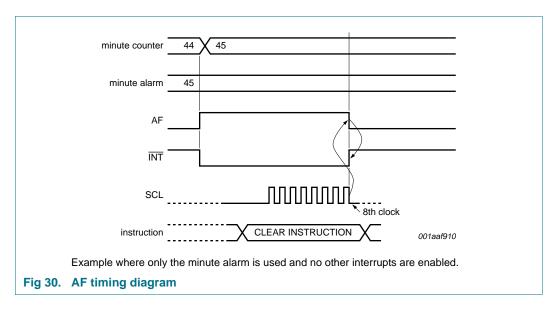
## 8.13.4 Watchdog timer interrupts

The generation of interrupts from the watchdog timer is controlled using the WD\_CD[1:0] bits (register Watchdg\_tim\_ctl). The interrupt is generated as an active signal which follows the status of the watchdog timer flag WDTF (register Control\_2). No pulse generation is possible for watchdog timer interrupts.

The interrupt is cleared when the flag WDTF is reset. WDTF is a read only bit and cannot be cleared by command. Instructions for clearing it can be found in Section 8.11.6.

#### 8.13.5 Alarm interrupts

Generation of interrupts from the <u>alarm</u> function is controlled by the bit AIE (register Control\_2). If AIE is enabled, the <u>INT</u> pin will follow the status of bit AF (register Control\_2). Clearing AF will immediately clear <u>INT</u>. No pulse generation is possible for alarm interrupts.



## Integrated RTC, TCXO and quartz crystal

## 8.13.6 Timestamp interrupts

Interrupt generation from the timestamp function is controlled using the TSIE bit (register Control\_2). If TSIE is enabled, the <a href="INT">INT</a> pin follows the status of the flags TSFx. Clearing the flags TSFx immediately clears <a href="INT">INT</a>. No pulse generation is possible for timestamp interrupts.

# 8.13.7 Battery switch-over interrupts

Generation of interrupts from the <u>battery</u> switch-over is controlled by the BIE bit (register Control\_3). If BIE is enabled, the <u>INT</u> pin follows the status of bit BF in register Control\_3 (see <u>Table 53</u>). Clearing BF immediately clears <u>INT</u>. No pulse generation is possible for battery switch-over interrupts.

## 8.13.8 Battery low detection interrupts

Generation of interrupts from the battery low detection is controlled by the BLIE bit (register Control\_3). If BLIE is enabled, the INT pin will follow the status of bit BLF (register Control\_3). The interrupt is cleared when the battery is replaced (BLF is logic 0) or when bit BLIE is disabled (BLIE is logic 0). BLF is read only and therefore cannot be cleared by command.

### Integrated RTC, TCXO and quartz crystal

#### 8.14 External clock test mode

A test mode is available which allows on-board testing. In this mode, it is possible to set up test conditions and control the operation of the RTC.

The test mode is entered by setting bit EXT\_TEST logic 1 (register Control\_1). Then pin CLKOUT becomes an input. The test mode replaces the internal clock signal (64 Hz) with the signal applied to pin CLKOUT. Every 64 positive edges applied to pin CLKOUT generate an increment of one second.

The signal applied to pin CLKOUT should have a minimum pulse width of 300 ns and a maximum period of 1000 ns. The internal clock, now sourced from CLKOUT, is divided down by a 2<sup>6</sup> divider chain called prescaler (see prescaler in <u>Table 56</u>). The prescaler can be set into a known state by using bit STOP. When bit STOP is logic 1, the prescaler is reset to 0. STOP must be cleared before the prescaler can operate again.

From a stop condition, the first 1 second increment will take place after 32 positive edges on pin CLKOUT. Thereafter, every 64 positive edges will cause a 1 second increment.

**Remark:** Entry into test mode is not synchronized to the internal 64 Hz clock. When entering the test mode, no assumption as to the state of the prescaler can be made.

Operating example:

- 1. Set EXT\_TEST test mode (register Control\_1, EXT\_TEST is logic 1).
- 2. Set bit STOP (register Control 1, STOP is logic 1).
- 3. Set time registers to desired value.
- 4. Clear STOP (register Control\_1, STOP is logic 0).
- 5. Apply 32 clock pulses to CLKOUT.
- 6. Read time registers to see the first change.
- 7. Apply 64 clock pulses to CLKOUT.
- 8. Read time registers to see the second change.

Repeat 7 and 8 for additional increments.

#### Integrated RTC, TCXO and quartz crystal

### 8.15 STOP bit function

The function of the STOP bit is to allow for accurate starting of the time circuits. STOP will cause the upper part of the prescaler ( $F_9$  to  $F_{14}$ ) to be held in reset and thus no 1 Hz ticks are generated. The time circuits can then be set and will not increment until the STOP bit is released. STOP will not affect the CLKOUT signal but the output of the prescaler in the range of 32 Hz to 1 Hz (see Figure 31).

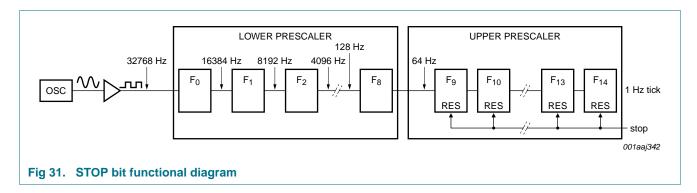
The lower stages of the prescaler,  $F_0$  to  $F_8$ , are not reset and because the  $I^2C$ -bus and the SPI-bus are asynchronous to the crystal oscillator, the accuracy of restarting the time circuits is between 0 and one 64 Hz cycle (0.484375 s and 0.500000 s), see <u>Table 56</u> and Figure 32.

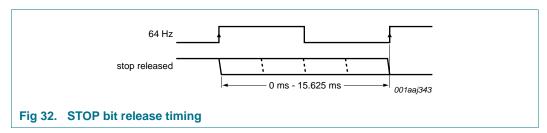
Table 56. First increment of time circuits after stop release

Bit STOP	Prescaler bits <sup>[1]</sup> F <sub>0</sub> to F <sub>8</sub> - F <sub>9</sub> to F <sub>14</sub>	1 Hz tick	Time hh:mm:ss	Comment
Clock is r	running normally			
0	010000111-010100		12:45:12	prescaler counting normally
STOP bit	is activated by user. F	o to F <sub>8</sub> are no	t reset and valu	es cannot be predicted externally
1	xxxxxxxx-000000		12:45:12	prescaler is reset; time circuits are frozen
New time	is set by user			
1	xxxxxxxx-00000		08:00:00	prescaler is reset; time circuits are frozen
STOP bit	is released by user			
0	xxxxxxxx-00000	σ  <b>I</b>	08:00:00	prescaler is now running
0	xxxxxxxx-100000		08:00:00	
0	xxxxxxxx-100000	- 0.500000	08:00:00	
0	xxxxxxxx-110000	75 - 0	08:00:00	
:	:	0.484375 -	:	
0	111111111-111110	_ ~; 	08:00:00	
0	000000000-000001	1	08:00:01	0 to 1 transition of $F_{14}$ increments the time circuits
0	100000000-000001	_   .	08:00:01	
:	:		` <u> </u>	
0	111111111-111111	ω	08:00:01	
0	000000000000000		08:00:01	
0	100000000-000000			
:	:		:	
0	111111111-111110	\	08:00:01	
0	000000000-00001		08:00:02	0 to 1 transition of F <sub>14</sub> increments the time circuits

<sup>[1]</sup> F<sub>0</sub> is clocked at 32.768 kHz.

# Integrated RTC, TCXO and quartz crystal





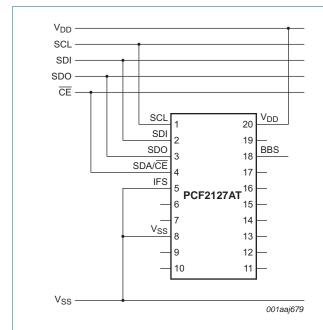
## Integrated RTC, TCXO and quartz crystal

## 9. Interfaces

The PCF2127AT has an  $I^2$ C-bus or SPI-bus interface using the same pins. The selection is done by the interface selection pin IFS (see <u>Table 57</u>).

Table 57. Interface selection input pin IFS

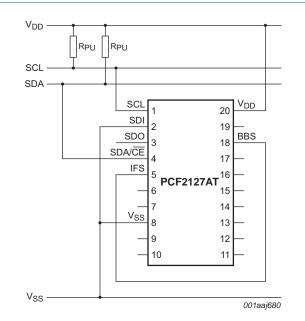
Pin	Connection	Bus interface	Reference
IFS	V <sub>SS</sub>	SPI-bus	Section 9.1
	BBS	I <sup>2</sup> C-bus	Section 9.2



To select the SPI-bus interface, pin IFS has to be connected to pin  $V_{SS}$ .

a. SPI-bus interface selection

Fig 33. Interface selection



To select the I<sup>2</sup>C-bus interface, pin IFS has to be connected to pin BBS.

b. I<sup>2</sup>C-bus interface selection

#### Integrated RTC, TCXO and quartz crystal

#### 9.1 SPI-bus interface

Data transfer to and from the device is made by a 3 line SPI-bus (see <u>Table 58</u>). The data lines for input and output are split. The data input and output line can be connected together to facilitate a bidirectional data bus (see <u>Figure 34</u>). The SPI-bus is initialized whenever the chip enable line pin SDA/CE is inactive.

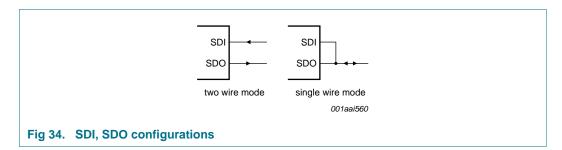


Table 58. Serial interface

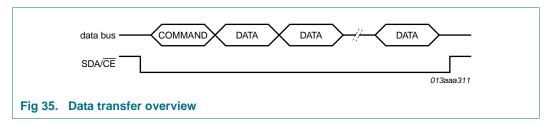
Symbol	Function	Description
SDA/CE	chip enable input;	when HIGH, the interface is reset;
	active LOW	input may be higher than $V_{\text{DD}}$
SCL	serial clock input	when SDA/CE is HIGH, input may float;
		input may be higher than $V_{\text{DD}}$
SDI	serial data input	when SDA/CE is HIGH, input may float;
		input may be higher than V <sub>DD</sub> ;
		input data is sampled on the rising edge of SCL
SDO	serial data output	push-pull output;
		drives from $V_{SS}$ to $V_{BBS}$ ;
		output data is changed on the falling edge of SCL

<sup>[1]</sup> The chip enable must not be wired permanently LOW.

### 9.1.1 Data transmission

The chip enable signal is used to identify the transmitted data. Each data transfer is a byte, with the Most Significant Bit (MSB) sent first.

The transmission is controlled by the active LOW chip enable signal SDA/CE. The first byte transmitted is the command byte. Subsequent bytes will be either data to be written or data to be read (see Figure 35).



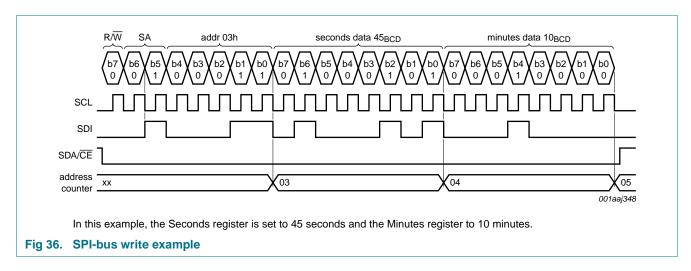
The command byte defines the address of the first register to be accessed and the read/write mode. The address counter will auto increment after every access and will reset to zero after the last valid register is accessed. The R/W bit defines if the following bytes will be read or write information.

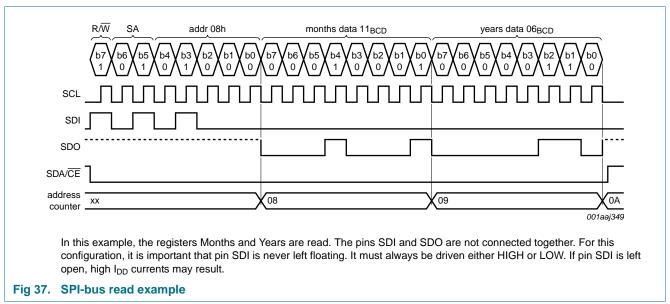
PCF2127AT

## Integrated RTC, TCXO and quartz crystal

Table 59. Command byte definition

Bit	Symbol	Value	Description
7	R/W		data read or write selection
		0	write data
		1	read data
6 to 5	SA	01	subaddress;
			other codes will cause the device to ignore data transfer
4 to 0	RA	00h to 1Dh	register address





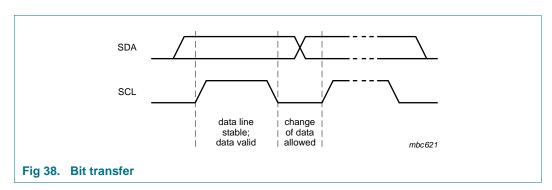
#### Integrated RTC, TCXO and quartz crystal

### 9.2 I<sup>2</sup>C-bus interface

The I<sup>2</sup>C-bus is for bidirectional, two-line communication between different ICs or modules. The two lines are a serial data line (SDA) and a serial clock line (SCL). Both lines are connected to a positive supply by a pull-up resistor. Data transfer is initiated only when the bus is not busy.

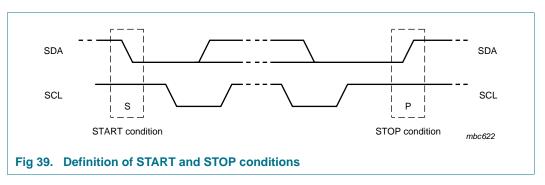
#### 9.2.1 Bit transfer

One data bit is transferred during each clock pulse. The data on the SDA line remains stable during the HIGH period of the clock pulse as changes in the data line at this time are interpreted as control signals (see Figure 38).



#### 9.2.2 START and STOP conditions

Both data and clock lines remain HIGH when the bus is not busy. A HIGH-to-LOW transition of the data line, while the clock is HIGH, is defined as the START condition S. A LOW-to-HIGH transition of the data line while the clock is HIGH is defined as the STOP condition P (see <u>Figure 39</u>).



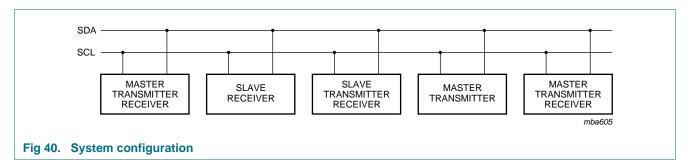
**Remark:** For the PCF2127AT, a repeated START is not allowed. Therefore a STOP has to be released before the next START.

## 9.2.3 System configuration

A device generating a message is a transmitter; a device receiving a message is the receiver. The device that controls the message is the master; and the devices which are controlled by the master are the slaves.

The PCF2127AT can act as a slave transmitter and a slave receiver.

#### Integrated RTC, TCXO and quartz crystal

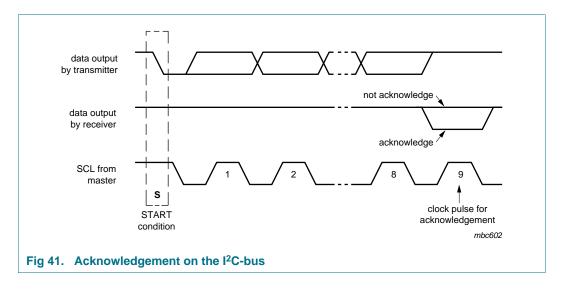


#### 9.2.4 Acknowledge

The number of data bytes transferred between the START and STOP conditions from transmitter to receiver is unlimited. Each byte of eight bits is followed by an acknowledge cycle.

- A slave receiver which is addressed must generate an acknowledge after the reception of each byte.
- Also a master receiver must generate an acknowledge after the reception of each byte that has been clocked out of the slave transmitter.
- The device that acknowledges must pull-down the SDA line during the acknowledge clock pulse, so that the SDA line is stable LOW during the HIGH period of the acknowledge related clock pulse (set-up and hold times must be considered).
- A master receiver must signal an end of data to the transmitter by not generating an acknowledge on the last byte that has been clocked out of the slave. In this event, the transmitter must leave the data line HIGH to enable the master to generate a STOP condition.

Acknowledgement on the I<sup>2</sup>C-bus is illustrated in Figure 41.



#### Integrated RTC, TCXO and quartz crystal

## 9.2.5 I<sup>2</sup>C-bus protocol

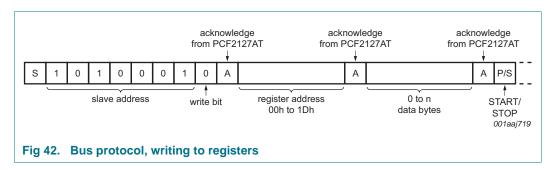
After a start condition, a valid hardware address has to be sent to a PCF2127AT device. The appropriate  $I^2C$ -bus slave address is 1010001. The entire  $I^2C$ -bus slave address byte is shown in Table 60.

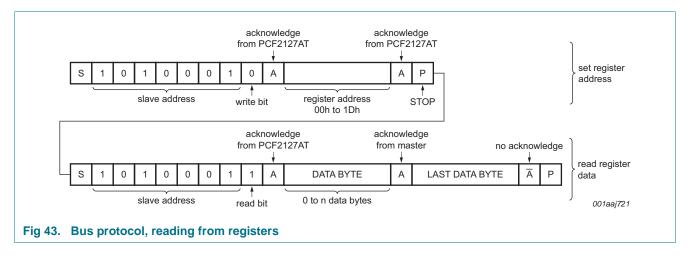
Table 60. I<sup>2</sup>C slave address byte

Bit	Slave address							
	7	6	5	4	3	2	1	0
	MSB							LSB
	1	0	1	0	0	0	1	$R/\overline{W}$

The  $R/\overline{W}$  bit defines the direction of the following single or multiple byte data transfer (read is logic 1, write is logic 0).

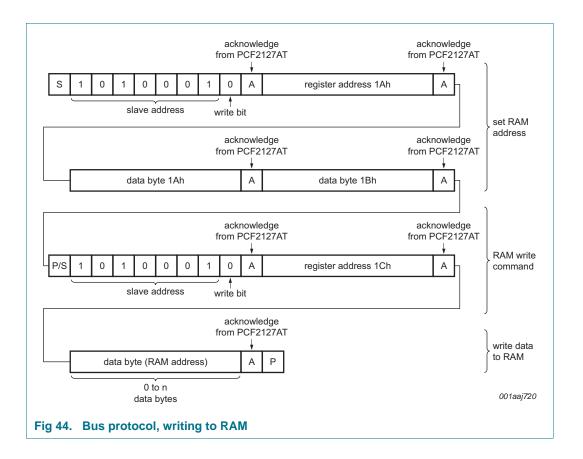
For the format and the timing of the START condition (S), the STOP condition (P), and the acknowledge bit (A) refer to the I<sup>2</sup>C-bus specification Ref. 11 "UM10204" and the characteristics table (Table 65). In the write mode, a data transfer is terminated by sending either a STOP condition or the START condition of the next data transfer.



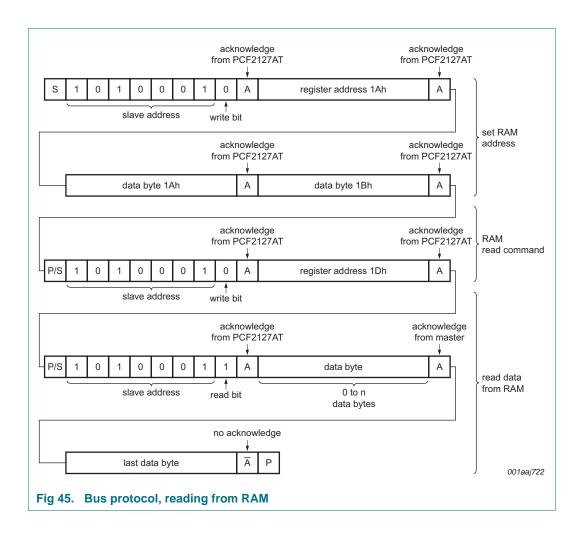


**PCF2127AT NXP Semiconductors** 

## Integrated RTC, TCXO and quartz crystal

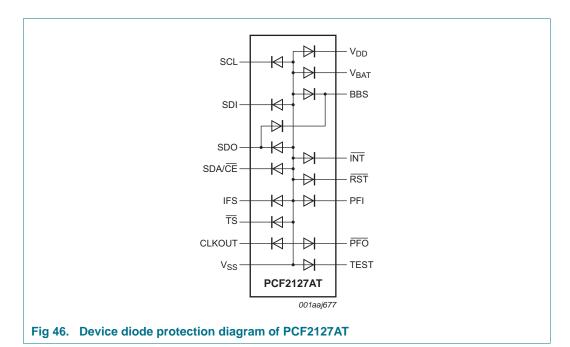


## Integrated RTC, TCXO and quartz crystal



Integrated RTC, TCXO and quartz crystal

# 10. Internal circuitry



## Integrated RTC, TCXO and quartz crystal

# 11. Limiting values

Table 61. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+6.5	V
I <sub>DD</sub>	supply current		-50	+50	mA
Vi	input voltage		-0.5	+6.5	V
I	input current		-10	+10	mA
Vo	output voltage		-0.5	+6.5	V
lo	output current		-10	+10	mA
		at pin SDA/CE	-10	+20	mA
$V_{BAT}$	battery supply voltage		-0.5	+6.5	V
P <sub>tot</sub>	total power dissipation		-	300	mW
$V_{ESD}$	electrostatic discharge	HBM	<u>[1]</u> -	±3500	V
	voltage	CDM	[2] _	±1500	V
I <sub>lu</sub>	latch-up current		[3] _	200	mA
T <sub>stg</sub>	storage temperature		<u>[4]</u> –55	+85	°C
T <sub>amb</sub>	ambient temperature	operating device	-40	+85	°C

<sup>[1]</sup> Pass level; Human Body Model (HBM) according to Ref. 7 "JESD22-A114".

<sup>[2]</sup> Pass level; Charged-Device Model (CDM), according to Ref. 8 "JESD22-C101".

<sup>[3]</sup> Pass level; latch-up testing according to Ref. 9 "JESD78" at maximum ambient temperature (T<sub>amb(max)</sub>).

<sup>[4]</sup> According to the store and transport requirements (see Ref. 12 "UM10569") the devices have to be stored at a temperature of +8 °C to +45 °C and a humidity of 25 % to 75 %.

# Integrated RTC, TCXO and quartz crystal

# 12. Static characteristics

Table 62. Static characteristics

 $V_{DD}$  = 1.8 V to 4.2 V;  $V_{SS}$  = 0 V;  $T_{amb}$  = -40 °C to +85 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
Supplies									
$V_{DD}$	supply voltage		<u>11</u> 1.8	-	4.2	V			
$V_{BAT}$	battery supply voltage		1.8	-	4.2	V			
V <sub>DD(cal)</sub>	calibration supply voltage		-	3.3	-	V			
$V_{low}$	low voltage		-	1.2	-	V			
I <sub>DD</sub>	supply current	interface active; supplied by V <sub>DD</sub>							
		SPI-bus ( $f_{SCL} = 6.5 \text{ MHz}$ )	-	-	800	μΑ			
		$I^2C$ -bus ( $f_{SCL} = 400 \text{ kHz}$ )	-	-	200	μΑ			
		interface inactive ( $f_{SCL} = 0 \text{ Hz}$ )[2] TCR[1:0] = 00 (see <u>Table 9 on page</u>							
		PWRMNG[2:0] = 111 (see <u>Table 18 on page 17</u> ); TSOFF = 1 (see <u>Table 46 on page 43</u> ); COF[2:0] = 111 (see <u>Table 11 on page 13</u> )							
		$V_{DD} = 2.0 \text{ V}$	-	500	-	nA			
		$V_{DD} = 3.3 \text{ V}$	-	700	1500	nA			
		$V_{DD} = 4.2 \text{ V}$	-	800	-	nA			
		PWRMNG[2:0] = 111 (see <u>Table 46 on p</u> TSOFF = 1 (see <u>Table 46 on p</u> COF[2:0] = 000 (see <u>Table 11</u>	age 43);	<u>17</u> );					
		$V_{DD} = 2.0 \text{ V}$	-	600	-	nA			
		$V_{DD} = 3.3 \text{ V}$	-	850	-	nA			
		$V_{DD} = 4.2 \text{ V}$	-	1050	-	nA			
		PWRMNG[2:0] = 000 (see <u>Table 16 on p</u> TSOFF = 0 (see <u>Table 46 on p</u> COF[2:0] = 111 (see <u>Table 11 or an annihilation p</u>	age 43);	<u>17</u> );					
		$V_{DD}$ or $V_{BAT} = 2.0 \text{ V}$	[3]	1800	-	nA			
		$V_{DD}$ or $V_{BAT} = 3.3 \text{ V}$	[3] _	2150	-	nA			
		$V_{DD}$ or $V_{BAT} = 4.2 \text{ V}$	[3] _	2350	3500	nA			
		PWRMNG[2:0] = 000 (see <u>Table 46 on p</u> TSOFF = 0 (see <u>Table 46 on p</u> COF[2:0] = 000 (see <u>Table 11</u>	age 43);	<u>17</u> );					
		$V_{DD}$ or $V_{BAT} = 2.0 \text{ V}$	[3]	1900	-	nA			
		$V_{DD}$ or $V_{BAT} = 3.3 \text{ V}$	[3]	2300	-	nA			
		$V_{DD}$ or $V_{BAT} = 4.2 \text{ V}$	[3]	2600	-	nA			
I <sub>L(bat)</sub>	battery leakage current	$V_{DD}$ is active supply; $V_{BAT} = 3.0 \text{ V}$	-	50	100	nA			

**PCF2127AT NXP Semiconductors** 

## Integrated RTC, TCXO and quartz crystal

Table 62. Static characteristics ... continued

 $V_{DD}$  = 1.8 V to 4.2 V;  $V_{SS}$  = 0 V;  $T_{amb}$  = -40 °C to +85 °C, unless otherwise specified.

Symbol	Parameter	Conditions	M	in	Тур	Max	Unit
Power ma	nagement						
$V_{th(sw)bat}$	battery switch threshold voltage		-		2.5	-	V
V <sub>th(bat)low</sub>	low battery threshold voltage		-		2.5	-	V
$V_{th(PFI)}$	threshold voltage on pin PFI		-		1.25	-	V
Inputs[4]							
VI	input voltage		-(	0.5	-	$V_{DD} + 0.5$	V
$V_{IL}$	LOW-level input voltage		-		-	0.25V <sub>DD</sub>	V
		$T_{amb}$ = -20 °C to +85 °C; $V_{DD}$ > 2.0 V	-		-		V
$V_{IH}$	HIGH-level input voltage		0.	$7V_{DD}$	-	-	V
I <sub>LI</sub>	input leakage current	$V_I = V_{DD}$ or $V_{SS}$	-		0	-	μΑ
		post ESD event		1	-	+1	μΑ
Ci	input capacitance		[5] _		-	7	pF
Outputs							
V <sub>O</sub>	output voltage	on pins CLKOUT, INT, RST, PFO, referring to external pull-up	-(	0.5	-	5.5	V
		on pin SDO	-(	0.5	-	- \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	V
I <sub>OL</sub>	LOW-level output current	output sink current; V <sub>OL</sub> = 0.4 V					
		on pin SDA/CE	<u>[6]</u> 3		17	-	mA
		on all other outputs	1.	0	-	-	mA
I <sub>OH</sub>	HIGH-level output current	output source current; on pin SDO; $V_{OH} = 3.8 \text{ V}$ ; $V_{DD} = 4.2 \text{ V}$	1.	0	-	-	mA
$I_{LO}$	output leakage current	$V_O = V_{DD}$ or $V_{SS}$	-		0	-	μΑ
		post ESD event	_′	1	-	+1	μΑ

<sup>[1]</sup> For reliable oscillator start-up at power-on:  $V_{DD(po)min} = V_{DD(min)} + 0.3 \text{ V}.$ 

<sup>[2]</sup> Timer source clock =  $\frac{1}{60}$  Hz, level of pins SDA/ $\overline{CE}$ , SDI, and SCL is  $V_{DD}$  or  $V_{SS}$ .

When the device is supplied by the V<sub>BAT</sub> pin instead of the V<sub>DD</sub> pin, the current values for I<sub>BAT</sub> will be as specified for I<sub>DD</sub> under the same conditions.

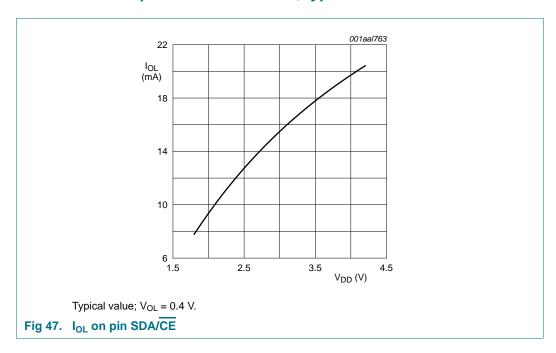
<sup>[4]</sup> The I<sup>2</sup>C-bus interface of PCF2127AT is 5 V tolerant.

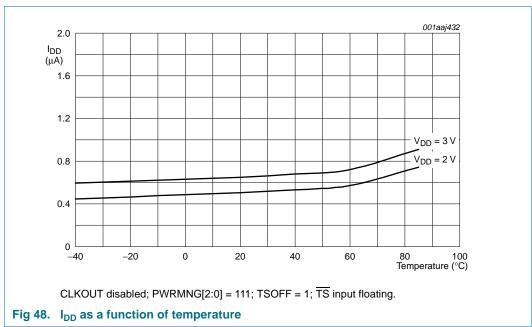
<sup>[5]</sup> Tested on sample basis.

<sup>[6]</sup> For further information, see Figure 47.

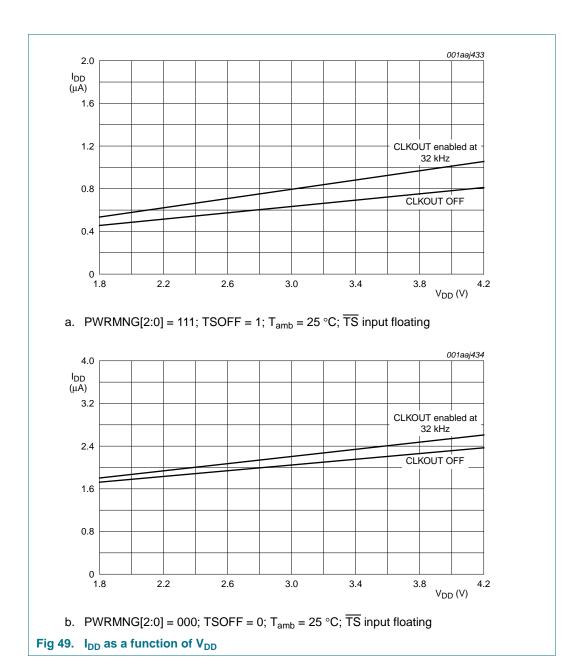
## Integrated RTC, TCXO and quartz crystal

# 12.1 Current consumption characteristics, typical





## Integrated RTC, TCXO and quartz crystal



## Integrated RTC, TCXO and quartz crystal

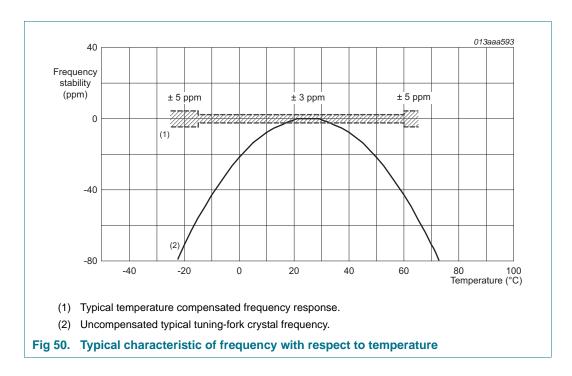
# 12.2 Frequency characteristics

Table 63. Frequency characteristics

 $V_{DD}$  = 1.8 V to 4.2 V;  $V_{SS}$  = 0 V;  $T_{amb}$  = +25 °C, unless otherwise specified.

טט	, oo , amb	,				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f <sub>o</sub>	output frequency	on pin CLKOUT; $V_{DD}$ or $V_{BAT} = 3.3 \text{ V}$ ; COF[2:0] = 000; AO[3:0] = 1000	-	32.768	-	kHz
∆f/f	frequency stability	$V_{DD}$ or $V_{BAT} = 3.3 \text{ V}$				
		$T_{amb} = -15  ^{\circ}\text{C} \text{ to +60 } ^{\circ}\text{C}$	[1][2]	±3	±5	ppm
		$T_{amb} = -25 ^{\circ}\text{C} \text{ to } -15 ^{\circ}\text{C}$ and $T_{amb} = +60 ^{\circ}\text{C} \text{ to } +65 ^{\circ}\text{C}$	<u>[1][2]</u> -	±5	±10	ppm
$\Delta f_{xtal}/f_{xtal}$	relative crystal frequency variation	crystal aging, first year; V <sub>DD</sub> or V <sub>BAT</sub> = 3.3 V	[3] _	-	±3	ppm
Δf/ΔV	frequency variation with voltage	on pin CLKOUT	-	±1	-	ppm/V

- [1]  $\pm 1$  ppm corresponds to a time deviation of  $\pm 0.0864$  seconds per day.
- [2] Only valid if CLKOUT frequencies are not equal to 32.768 kHz or if CLKOUT is disabled.
- [3] Not production tested. Effects of reflow solder not included (see Ref. 3 "AN10857").



Integrated RTC, TCXO and quartz crystal

# 13. Dynamic characteristics

# 13.1 SPI-bus timing characteristics

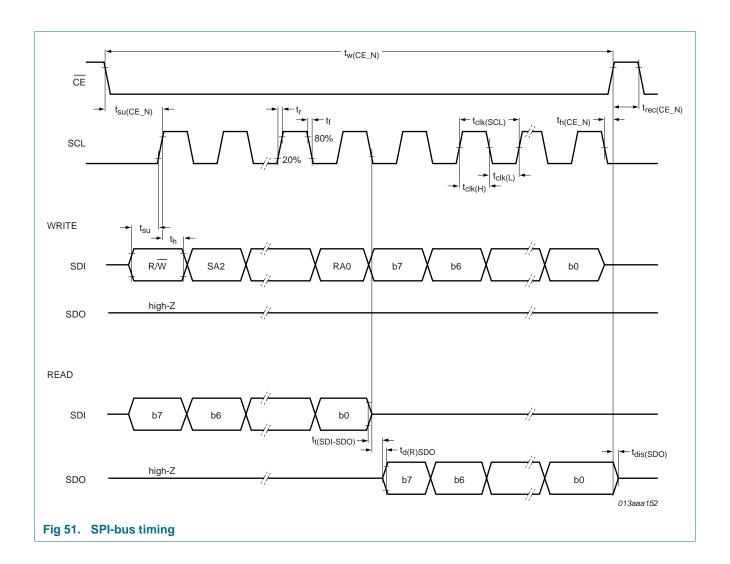
Table 64. SPI-bus characteristics

 $V_{DD} = 1.8 \text{ V}$  to 4.2 V;  $V_{SS} = 0 \text{ V}$ ;  $T_{amb} = -40 \,^{\circ}\text{C}$  to +85  $^{\circ}\text{C}$ , unless otherwise specified. All timing values are valid within the operating supply voltage at ambient temperature and referenced to  $V_{IL}$  and  $V_{IH}$  with an input voltage swing of  $V_{SS}$  to  $V_{DD}$ .

Symbol	Parameter	Conditions	$V_{DD} = 1$	I.8 V	$V_{DD} = 4.2 V$		Unit
			Min	Max	Min	Max	
Pin SCL							
f <sub>clk(SCL)</sub>	SCL clock frequency	register read/write access	-	2.0	-	6.5	MHz
		RAM write access	-	2.0	-	6.5	MHz
		RAM read access	-	1.11	-	6.25	MHz
t <sub>SCL</sub>	SCL time	register read/write access	800	-	140	-	ns
		RAM write access	800	-	140	-	ns
		RAM read access	900	-	160	-	ns
t <sub>clk(H)</sub>	clock HIGH time	register read/write access	100	-	70	-	ns
		RAM write access	100	-	70	-	ns
		RAM read access	450	-	80	-	MH:  MH:  ns  ns  ns  ns  ns  ns  ns  ns  ns  n
t <sub>clk(L)</sub>	clock LOW time	register read/write access	400	-	70	-	ns
		RAM write access	400	-	70	-	ns
		RAM read access	450	-	80	-	ns ns ns ns
t <sub>r</sub>	rise time	for SCL signal	-	100	-	30	ns
t <sub>f</sub>	fall time	for SCL signal	-	100	-	30	ns
Pin SDA/	E						
t <sub>su(CE_N)</sub>	CE_N set-up time		60	-	30	-	ns
t <sub>h(CE_N)</sub>	CE_N hold time		40	-	25	-	ns
t <sub>rec(CE_N)</sub>	CE_N recovery time		100	-	30	-	ns
t <sub>w(CE_N)</sub>	CE_N pulse width		-	0.99	-	0.99	S
Pin SDI							
t <sub>su</sub>	set-up time	set-up time for SDI data	70	-	20	-	ns
t <sub>h</sub>	hold time	hold time for SDI data	70	-	20	-	ns
Pin SDO							
t <sub>d(R)SDO</sub>	SDO read delay time	C <sub>L</sub> = 50 pF					
		register read access	-	225	-	55	ns
		RAM read access	-	410	-	55	ns
t <sub>dis(SDO)</sub>	SDO disable time	[1]	-	90	-	25	ns
t <sub>t(SDI-SDO)</sub>	transition time from SDI to SDO	to avoid bus conflict	0	-	0	-	ns

<sup>[1]</sup> No load value; bus will be held up by bus capacitance; use RC time constant with application values.

# Integrated RTC, TCXO and quartz crystal



## Integrated RTC, TCXO and quartz crystal

## 13.2 I<sup>2</sup>C interface timing characteristics

#### Table 65. I<sup>2</sup>C-bus characteristics

All timing characteristics are valid within the operating supply voltage and ambient temperature range and reference to 30 % and 70 % with an input voltage swing of  $V_{SS}$  to  $V_{DD}$  (see <u>Figure 52</u>).

Symbol	Parameter		Standard mode		Fast-mode	(Fm)	Unit
			Min	Max	Min	Max	
Pin SCL							
f <sub>SCL</sub>	SCL clock frequency	<u>[1]</u>	0	100	0	400	kHz
t <sub>LOW</sub>	LOW period of the SCL clock		4.7	-	1.3	-	μS
t <sub>HIGH</sub>	HIGH period of the SCL clock		4.0	-	0.6	-	μS
Pin SDA	/CE						
t <sub>SU;DAT</sub>	data set-up time		250	-	100	-	ns
t <sub>HD;DAT</sub>	data hold time		0	-	0	-	ns
Pins SC	L and SDA/CE						
t <sub>BUF</sub>	bus free time between a STOP and START condition		4.7	-	1.3	-	μS
t <sub>SU;STO</sub>	set-up time for STOP condition		4.0	-	0.6	-	μS
t <sub>HD;STA</sub>	hold time (repeated) START condition		4.0	-	0.6	-	μS
t <sub>SU;STA</sub>	set-up time for a repeated START condition		4.7	-	0.6	-	μS
t <sub>r</sub>	rise time of both SDA and SCL signals	[2][3][4]	-	1000	20 + 0.1C <sub>b</sub>	300	ns
t <sub>f</sub>	fall time of both SDA and SCL signals	[2][3][4]	-	300	20 + 0.1C <sub>b</sub>	300	ns
t <sub>VD;ACK</sub>	data valid acknowledge time	<u>[5]</u>	0.1	3.45	0.1	0.9	μS
$t_{VD;DAT}$	data valid time	<u>[6]</u>	300	-	75	-	ns
t <sub>SP</sub>	pulse width of spikes that must be suppressed by the input filter	[7]	-	50	-	50	ns

<sup>[1]</sup> The minimum SCL clock frequency is limited by the bus time-out feature which resets the serial bus interface if either the SDA or SCL is held LOW for a minimum of 25 ms. The bus time-out feature must be disabled for DC operation.

<sup>[2]</sup> A master device must internally provide a hold time of at least 300 ns for the SDA signal (refer to the V<sub>IL</sub> of the SCL signal) in order to bridge the undefined region of the falling edge of SCL.

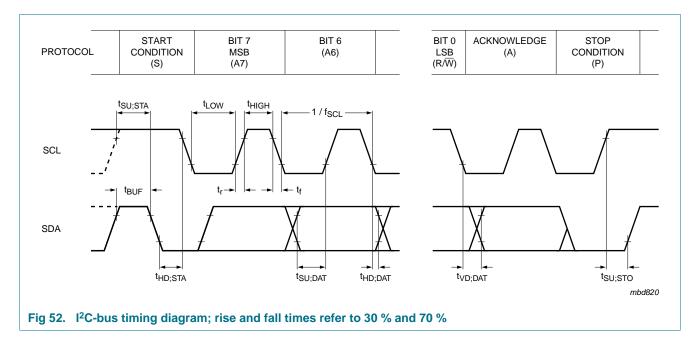
<sup>[4]</sup> The maximum  $t_f$  for the SDA and SCL bus lines is 300 ns. The maximum fall time for the SDA output stage,  $t_f$  is 250 ns. This allows series protection resistors to be connected between the SDA/ $\overline{\text{CE}}$  pin, the SCL pin, and the SDA/SCL bus lines without exceeding the maximum  $t_f$ .

<sup>[5]</sup>  $t_{VD;ACK}$  is the time of the acknowledgement signal from SCL LOW to SDA (out) LOW.

<sup>6]</sup> t<sub>VD:DAT</sub> is the minimum time for valid SDA (out) data following SCL LOW.

 $<sup>\</sup>cite{Model}$  Input filters on the SDA and SCL inputs suppress noise spikes of less than 50 ns.

### Integrated RTC, TCXO and quartz crystal



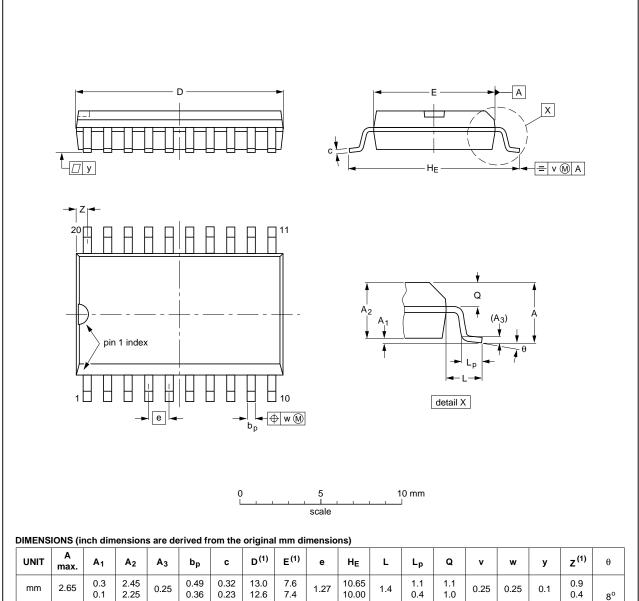
## 14. Application information

For information about application configuration see Ref. 3 "AN10857".

## 15. Package outline

#### SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	z <sup>(1)</sup>	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013				<del>99-12-27</del> 03-02-19

Fig 53. Package outline SOT163-1 (SO20)

PCF2127AT

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## 16. Packing information

### 16.1 Carrier tape information

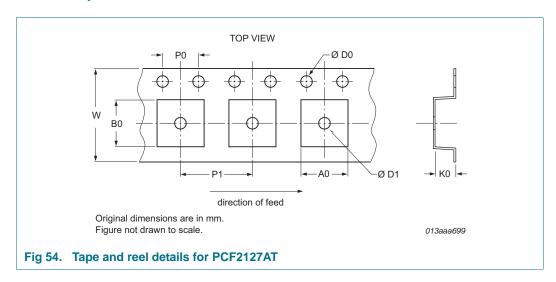


Table 66. Carrier tape dimensions of PCF2127AT

Symbol	Description	Value	Unit			
Compartment	s					
A0	pocket width in x direction	10.8 to 10.9	mm			
В0	pocket width in y direction	13.3 to 13.4	mm			
K0	pocket depth	2.70 to 2.85	mm			
P1	pocket hole pitch	12.0	mm			
D1	pocket hole diameter	1.5 to 2.05	mm			
Overall dimen	Overall dimensions					
W	tape width	24.0	mm			
D0	sprocket hole diameter	1.5 to 1.55	mm			
P0	sprocket hole pitch	4.0	mm			

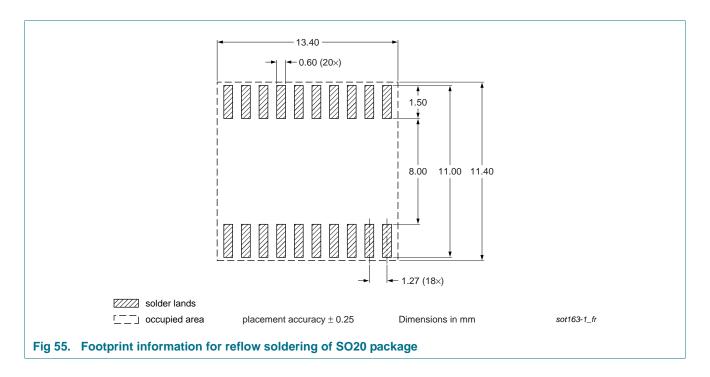
## 17. Soldering

For information about soldering see Ref. 3 "AN10857".

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### Integrated RTC, TCXO and quartz crystal

## 18. Footprint information



### Integrated RTC, TCXO and quartz crystal

## 19. Abbreviations

Table 67. Abbreviations

Table 01. Abbie	viation3
Acronym	Description
AM	Ante Meridiem
BCD	Binary Coded Decimal
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DC	Direct Current
GPS	Global Positioning System
НВМ	Human Body Model
I <sup>2</sup> C	Inter-Integrated Circuit
IC	Integrated Circuit
LSB	Least Significant Bit
MCU	Microcontroller Unit
MM	Machine Model
MSB	Most Significant Bit
PM	Post Meridiem
POR	Power-On Reset
PORO	Power-On Reset Override
PPM	Parts Per Million
RAM	Random Access Memory
RC	Resistance-Capacitance
RTC	Real Time Clock
SCL	Serial CLock line
SDA	Serial DAta line
SPI	Serial Peripheral Interface
SRAM	Static Random Access Memory
TCXO	Temperature Compensated Xtal Oscillator
Xtal	crystal

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#### Integrated RTC, TCXO and quartz crystal

#### 20. References

- **AN10365** Surface mount reflow soldering description [1]
- [2] AN10853 — Handling precautions of ESD sensitive devices
- AN10857 Application and soldering information for PCF2127A and PCF2129A [3] TCXO RTC
- [4] IEC 60134 — Rating systems for electronic tubes and valves and analogous semiconductor devices
- [5] **IEC 61340-5** — Protection of electronic devices from electrostatic phenomena
- IPC/JEDEC J-STD-020D Moisture/Reflow Sensitivity Classification for [6] Nonhermetic Solid State Surface Mount Devices
- [7] JESD22-A114 — Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)
- **JESD22-C101** Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components
- JESD78 IC Latch-Up Test [9]
- [10] JESD625-A Requirements for Handling Electrostatic-Discharge-Sensitive (ESDS) Devices
- [11] UM10204 I<sup>2</sup>C-bus specification and user manual
- [12] UM10569 Store and transport requirements

### Integrated RTC, TCXO and quartz crystal

## 21. Revision history

#### Table 68. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PCF2127AT v.3	20121004	Product data sheet	-	PCF2127A v.2			
Modifications:	<ul> <li>Enhanced d</li> </ul>	escription of I <sub>DD</sub> values ( <u>Tab</u>	ole 62)				
	<ul> <li>Added ordering options (<u>Section 4.1</u>)</li> </ul>						
<ul> <li>Added footprint information (<u>Figure 55</u>)</li> </ul>							
PCF2127A v.2	20100507	Product data sheet	-	PCF2127A v.1			
PCF2127A v.1	20100121	Product data sheet	-	-			

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### 22. Legal information

#### 22.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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#### Integrated RTC, TCXO and quartz crystal

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## Integrated RTC, TCXO and quartz crystal

## 24. Tables

Table 1.	Ordering information2		register (address 10h) bit description	36
Table 2.	Ordering options2	Table 36.	Watchdg_tim_val - watchdog timer value	
Table 3.	Marking codes2		register (address 11h) bit description	37
Table 4.	Pin description of SO20 (PCF2127AT)4	Table 37.	Programmable watchdog or countdown	
Table 5.	Register overview7		timer	37
Table 6.	Control_1 - control and status register 1		Specification of t <sub>w(rst)</sub>	
	(address 00h) bit description9		First period delay for timer counter	
Table 7.	Control_2 - control and status register 2		Flag location in register Control_2	
	(address 01h) bit description10		Example values in register Control_2	41
Table 8.	Control_3 - control and status register 3	Table 42.	Example to clear only CDTF (bit 3)	
	(address 02h) bit description		in register Control_2	41
Table 9.	CLKOUT_ctl - CLKOUT control register	Table 43.	Example to clear only AF (bit 4)	
<b>-</b>	(address 0Fh) bit description	<b>-</b>	in register Control_2	41
	Temperature measurement period	Table 44.	Example to clear only MSF (bit 7)	
	CLKOUT frequency selection	T-1-1- 45	in register Control_2	41
Table 12.	Aging_offset - crystal aging offset register	Table 45.	Example to clear both CDTF and MSF	4.4
Table 40	(address 19h) bit description	Table 40	in register Control_2	41
	Frequency correction at 25 °C, typical	Table 46.	Timestp_ctl - timestamp control register	40
Table 14.	RAM_addr_MSB - RAM address MSB	Table 47	(address 12h) bit description	43
Toblo 15	register (address 1Ah) bit description15	Table 47.	Sec_timestp - second timestamp register	40
Table 15.	RAM_addr_LSB - RAM address LSB	Table 49	(address 13h) bit description	43
Table 16	register (address 1Bh) bit description15 RAM_wrt_cmd - RAM write command	Table 40.	(address 14h) bit description	45
Table 10.	register (address 1Ch) bit description15	Table 40	Hour_timestp - hour timestamp register	40
Tahla 17	RAM_rd_cmd - RAM read command	Table 49.	(address 15h) bit description	1/
Table 17.	register (address 1Dh) bit description	Table 50	Day_timestp - day timestamp register	
Tahla 18	Power management control bit description 17	Table 30.	(address 16h) bit description	44
	Output pin BBS	Table 51	Mon_timestp - month timestamp register	
	Seconds - seconds and clock integrity	14510 01.	(address 17h) bit description	44
10010 20.	register (address 03h) bit description	Table 52	Year_timestp - year timestamp register	
Table 21.	Seconds coded in BCD format29	14510 02.	(address 18h) bit description	44
	Minutes - minutes register (address 04h)	Table 53.	Battery switch-over and timestamp	
	bit description		Effect of bits MI and SI on pin INT and	
Table 23.	Hours - hours register (address 05h)		bit MSF	47
	bit description30	Table 55.	INT operation (bit TI_TP = 1)	
Table 24.	Days - days register (address 06h)		First increment of time circuits after	
	bit description		stop release	53
Table 25.	Weekdays - weekdays register	Table 57.	Interface selection input pin IFS	
	(address 07h) bit description30		Serial interface	
	Weekday assignments		Command byte definition	
Table 27.	Months - months register (address 08h)	Table 60.	I <sup>2</sup> C slave address byte	60
	bit description		Limiting values	
	Month assignments in BCD format31		Static characteristics	
Table 29.	Years - years register (address 09h)		Frequency characteristics	
	bit description		SPI-bus characteristics	
Table 30.	Second_alarm - second alarm register		I <sup>2</sup> C-bus characteristics	
	(address 0Ah) bit description		Carrier tape dimensions of PCF2127AT	
Table 31.	Minute_alarm - minute alarm register		Abbreviations	
	(address 0Bh) bit description	Table 68.	Revision history	79
Table 32.	Hour_alarm - hour alarm register			
	(address 0Ch) bit description			
iable 33.	Day_alarm - day alarm register			
Toble 24	(address 0Dh) bit description			
1able 34.	Weekday_alarm - weekday alarm register			
Table 25	(address 0Eh) bit description			
iadie 35.	Watchdg_tim_ctl - watchdog timer control			

82 of 85

## Integrated RTC, TCXO and quartz crystal

## 25. Figures

Fig 1.	Block diagram of PCF2127AT	3
Fig 2.	Pin configuration for SO20 (PCF2127AT)	
Fig 3.	Handling address registers	
Fig 4.	Battery switch-over behavior in standard mode	0
1 19 <del>1</del> .	with bit BIE set logic 1 (enabled)	10
Eia 5	Battery switch-over behavior in direct switching	. 13
Fig 5.		20
F: 0	mode with bit BIE set logic 1 (enabled)	.20
Fig 6.	Battery switch-over circuit, simplified block	0.4
	diagram	.21
Fig 7.	Typical driving capability of $V_{BBS}$ : $(V_{BBS} - V_{DD})$	
	with respect to the output load current $I_{\mbox{\footnotesize BBS}} \ldots$	.22
Fig 8.	Battery low detection behavior with bit BLIE	
	set logic 1 (enabled)	.23
Fig 9.	Typical application of the extra power fail	
	detection function	.23
Fig 10.	PFO signal behavior when battery	
	switch-over is enabled in standard mode and	
	$V_{th(uvp)} > (V_{BAT}, V_{th(sw)bat}) \dots \dots$	.24
Fig 11.	PFO signal behavior when battery switch-over is	
Ü	enabled in direct switching mode and V <sub>th(uvp)</sub>	
	< V <sub>BAT</sub>	.25
Fig 12.	PFO signal behavior when battery switch-over	
9	is disabled	25
Fig 13.	Power failure event due to battery discharge:	0
1 ig 10.	reset occurs	26
Fig 14.	Dependency between POR and oscillator	
Fig 15.	Power-On Reset (POR) system	
Fig 16.		.20
rig io.	Power-On Reset Override (PORO) sequence,	20
F: 47	valid for both I <sup>2</sup> C-bus and SPI-bus	
Fig 17.	Data flow of the time function	
Fig 18.	Access time for read/write operations	
Fig 19.	Alarm function block diagram	
Fig 20.	Alarm flag timing diagram	.35
Fig 21.	WD_CD[1:0] = 10: watchdog activates an	
	interrupt when timed out	.38
Fig 22.	WD_CD[1:0] = 11: watchdog activates a reset	
	pulse when timed out	.38
Fig 23.	General countdown timer behavior	.39
Fig 24.	Timestamp detection with two push-buttons	
	on the TS pin (for example,	
	for tamper detection)	.42
Fig 25.	Interrupt block diagram	.46
Fig 26.	INT example for SI and MI when TI_TP is	
J	logic 1	.48
Fig 27.	INT example for SI and MI when TI_TP is	
9	logic 0	48
Fig 28.	Example of shortening the INT pulse by	
. ig 20.	clearing the MSF flag	49
Fig 29.	Example of shortening the INT pulse by	.40
1 lg 23.	clearing the CDTF flag	50
Eig 20		
Fig 30.	AF timing diagram	
Fig 31.	STOP bit release timing	
Fig 32.	STOP bit release timing	
Fig 33.	Interface selection	
Fig 34.	SDI, SDO configurations	
-IU 32	Data transfer overview	56

Fig 36.	SPI-bus write example5	7
ig 37.	SPI-bus read example5	7
ig 38.	Bit transfer5	8
ig 39.	Definition of START and STOP conditions 5	8
ig 40.	System configuration5	9
ig 41.	Acknowledgement on the I <sup>2</sup> C-bus5	9
Fig 42.	Bus protocol, writing to registers 6	0
Fig 43.	Bus protocol, reading from registers 6	0
Fig 44.	Bus protocol, writing to RAM6	1
Fig 45.	Bus protocol, reading from RAM6	2
Fig 46.	Device diode protection diagram of PCF2127AT 6	
Fig 47.	I <sub>OL</sub> on pin SDA/CE 6	
Fig 48.	I <sub>DD</sub> as a function of temperature 6	
Fig 49.	I <sub>DD</sub> as a function of V <sub>DD</sub> 6	8
Fig 50.	Typical characteristic of frequency	
	with respect to temperature6	9
Fig 51.	SPI-bus timing7	1
Fig 52.	I <sup>2</sup> C-bus timing diagram; rise and fall times	
	refer to 30 % and 70 %	
Fig 53.	Package outline SOT163-1 (SO20)7	4
Fig 54.	Tape and reel details for PCF2127AT 7	5
Fig 55.	Footprint information for reflow soldering of	
	SO20 package7	6

PCF2127AT

### Integrated RTC, TCXO and quartz crystal

## 26. Contents

1	General description	. 1	8.8.1	Power-On Reset (POR)	27
2	Features and benefits	. 1	8.8.2	Power-On Reset Override (PORO)	27
3	Applications		8.9	Time and date function	29
	Ordering information		8.9.1	Register Seconds	
4			8.9.2	Register Minutes	29
4.1	Ordering options		8.9.3	Register Hours	30
5	Marking	. 2	8.9.4	Register Days	30
6	Block diagram	. 3	8.9.5	Register Weekdays	30
7	Pinning information	. 4	8.9.6	Register Months	
7.1	Pinning		8.9.7	Register Years	
7.2	Pin description		8.9.8	Setting and reading the time	
8	Functional description		8.10	Alarm function	
8.1	Register overview		8.10.1	Register Second_alarm	
8.2	Control registers		8.10.2	Register Minute_alarm	
8.2.1	Register Control_1		8.10.3	Register Hour_alarm	
8.2.2	Register Control_2		8.10.4	Register Day_alarm	
8.2.3	Register Control_3		8.10.5	Register Weekday_alarm	
8.3	Register CLKOUT_ctl		8.10.6	Alarm flag	
8.3.1	Temperature compensated crystal oscillator .		8.11	Timer functions	
8.3.1.1	Temperature measurement		8.11.1	Register Watchdg_tim_ctl	
8.3.2	Clock output		8.11.2	Register Watchdg_tim_val	
8.4	Register Aging_offset		8.11.3	Watchdog timer function	
8.4.1	Crystal aging correction		8.11.4	Countdown timer function	39
8.5	General purpose 512 bytes static RAM	15	8.11.5	Pre-defined timers: second and minute	
8.5.1	Register RAM_addr_MSB			interrupt	
8.5.2	Register RAM_addr_LSB		8.11.6	Clearing flags	
8.5.3	Register RAM_wrt_cmd		8.12	Timestamp function	
8.5.4	Register RAM_rd_cmd		8.12.1	Timestamp flag	
8.5.5	Operation examples		8.12.2	Time stamp mode	
8.5.5.1	Writing to the RAM		8.12.3	Timestamp registers	
8.5.5.2	Reading from the RAM		8.12.3.1	Register Timestp_ctl	
8.6	Power management functions		8.12.3.2	Register Sec_timestp	
8.6.1	Battery switch-over function		8.12.3.3	Register Min_timestp	
8.6.1.1	Standard mode		8.12.3.4	Register Hour_timestp	
8.6.1.2	Direct switching mode		8.12.3.5	Register Day_timestp	
8.6.1.3	Battery switch-over disabled: only one		8.12.3.6	Register Mon_timestp	
	power supply (V <sub>DD</sub> )	20	8.12.3.7	Register Year_timestp	44
8.6.1.4	Battery switch-over architecture		8.12.4	Dependency between Battery switch-over	15
8.6.2	Battery backup supply		0.40	and timestamp	
8.6.3	Battery low detection function		8.13 8.13.1	Interrupt output, INT Minute and second interrupts	
8.6.4	Extra power fail detection function	23			
8.6.4.1	Extra power fail detection when the battery		8.13.2 8.13.3	Countdown timer interrupts	
	switch over function is enabled	24	8.13.4	INT pulse shortening	
8.6.4.2	Extra power fail detection when the battery		8.13. <del>4</del> 8.13.5	Watchdog timer interrupts	
	switch-over function is disabled		8.13.6	Timestamp interrupts	
8.7	Oscillator stop detection function	26	8.13.7	Battery switch-over interrupts	
8.8	Reset function		8.13.8	Battery low detection interrupts	

continued >>

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# **PCF2127AT**

### Integrated RTC, TCXO and quartz crystal

8.14 8.15	STOP bit function	52 53
9	Interfaces	55
9.1	SPI-bus interface	56
9.1.1	Data transmission	56
9.2	I <sup>2</sup> C-bus interface	58
9.2.1	Bit transfer	58
9.2.2	START and STOP conditions	58
9.2.3	System configuration	58
9.2.4	Acknowledge	59
9.2.5	I <sup>2</sup> C-bus protocol	60
10	Internal circuitry	63
11	Limiting values	64
12	Static characteristics	65
12.1	Current consumption characteristics, typical .	67
12.2	Frequency characteristics	69
13	Dynamic characteristics	70
13.1	SPI-bus timing characteristics	70
13.2	I <sup>2</sup> C interface timing characteristics	72
14	Application information	73
15	Package outline	74
16	Packing information	75
16.1	Carrier tape information	75
17	Soldering	75
18	Footprint information	76
19	Abbreviations	77
20	References	78
21	Revision history	79
22	Legal information	80
22.1	Data sheet status	80
22.2	Definitions	80
22.3	Disclaimers	80
22.4	Trademarks	81
23	Contact information	81
24	Tables	82
25	Figures	83
26	Contents	84

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